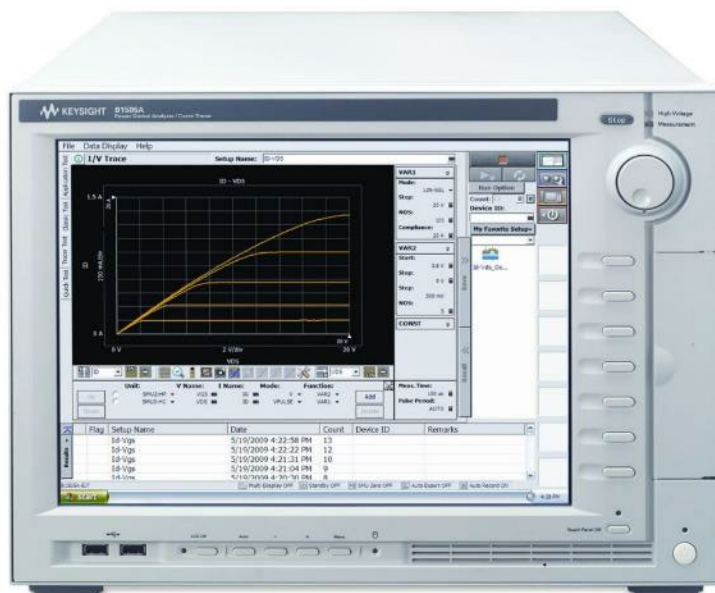


B1505A

Power device analyzer / Curve tracer

Introduction

The Keysight Technologies, Inc. B1505A Power Device Analyzer/Curve Tracer is a single-box solution with next-generation curve tracer functionality that can accurately evaluate and characterize power devices at up to 10 kV and 1500 A.



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Product Overview

The B1505A can handle all types of power device evaluation, with features that include a wide voltage and current range, fast pulsing capability (10 μ s), $\mu\Omega$ level on-resistance measurement resolution, and sub-pA level current measurement capability. In addition, an oscilloscope view permits visual verification of current and voltage-pulsed waveforms.

Two independent Analog-to-Digital (A/D) converters on each channel support a 2 μ s sampling rate to monitor the critical timings that can affect device behavior accurately.

It can also perform fully automated capacitance measurements (such as Ciss, Coss, and Crss) at high voltage biases (up to 3 kV). Moreover, it can also evaluate gate charge (an important parameter for high-frequency switching converter efficiency) at up to 3 kV.

The B1505A with EasyEXPERT group+ software includes a curve tracer mode that combines familiar curve tracer functionality with the convenience of a PC-based instrument; this makes it easy for traditional curve-tracer users to become productive quickly.

Module selector, device capacitance selector, and Quick Test feature enable fully automated measurement on multiple parameters without re-cabling.

Keysight EasyEXPERT group+ GUI-based characterization software is available either on the B1505A's embedded Windows 10 platform with a 15-inch touch screen or on your PC to accelerate the characterization tasks. It supports efficient and repeatable device characterization in the entire characterization process from measurement setup and execution to analysis and data management, either interactive manual operation or automation across a wafer in conjunction with a semiautomatic wafer prober.

EasyEXPERT group+ makes it easy to perform complex device characterization immediately with hundreds of ready-to-use measurements (application tests) furnished and allows you the option of storing test condition and measurement data automatically after each measurement in a unique built-in database (workspace), ensuring that valuable information is not lost and that measurements can be repeated at a later date. The net result is improved ease of use, better data analysis, and simplified data management to measure power devices and power circuitry.

Basic features

Precision measurement across a wide range of operating conditions

- All-in-one solution for power device characterization up to 1500 A/10 kV
- Medium current measurement with high voltage bias (e.g., 500 mA at 1200 V).
- $\mu\Omega$ resistance measurement capability
- Accurate sub-picoamp level current measurement at high voltage bias
- Fully automated thermal test from -50 to +250 °C

Extensive device evaluation capabilities

- Fully automated Capacitance (Ciss, Coss, Crss, etc.) measurement at up to 3000 V of DC bias
- High-power pulsed measurements down to 10 μ s
- Gate charge measurement covering Nch MOSFETs and IGBTs both in a package and on a wafer
- High voltage/high current fast switch option to characterize GaN current collapse effect
- Up to 5 high voltage (3 kV) source/measure unit channels for reliability applications
- Perform both hot and cold temperature dependency testing in an interlock-equipped test fixture
- Support SiC MOSFET Vth, BTI-Vth measurements based on the JEDEC standards

Improved measurement efficiency

- Switch between high-voltage and high-current measurements without the need to re-cable
- Automated reconfiguration of test circuitry for transistor capacitance measurement (Ciss, Coss, Crss, Cgs, Cgd, Cds, etc.) for both packaged and on-wafer devices
- Standard test fixtures with interlock for safe packaged power device testing
- Supported and secure on-wafer high-power
- The Oscilloscope view allows verification of applied voltage and current waveforms
- MS Windows-based EasyEXPERT group+ software facilitates data management and simplifies data analysis

Upgradable and scalable hardware architecture

- A wide selection of measurement modules
- Support for high-power devices with up to 6 pins

GPIO, USB, LAN interfaces, and VGA video output port

Self-test, self-calibration, diagnostics

Specification conditions

The measurement and output accuracy are specified under the conditions listed below. Note: The SMU measurement and output accuracies are specified at the SMU connector terminals, using the Zero Check terminal as a reference.

1. Temperature: 23 ± 5 °C
2. Humidity: 20 to 70%
3. Self-calibration after a 40-minute warm-up is required.
4. Ambient temperature changes less than ± 1 °C after self-calibration execution. (Note: This does not apply to the MFCMU).
5. Measurement made within one hour after self-calibration execution. (Note: This does not apply to the MFCMU).
6. Calibration period: 1 year
7. SMU integration time setting: 1 PLC (1 nA to 1 A range, voltage range), 200 μ s (20 A range).
Averaging of high-speed ADC: 128 samples per 1 PLC
8. SMU filter: ON (for HPSMU and MPSMU)
9. SMU measurement terminal connection: Kelvin connection (for HPSMU, MPSMU, HCSMU, and MCSMU), non-Kelvin (for HVSMU)

Note: This document lists specifications and supplemental characteristics for the B1505A and its associated modules. The specifications are the standards against which the B1505A and its associated modules are tested. When the B1505A or any of its associated modules are shipped from the factory, they meet the specifications. The "supplemental" characteristics described in the following specifications are not guaranteed but provide useful information about the functions and performance of the instrument.

Note: Module upgrades to existing B1505A systems must be carried out at a Keysight Technologies, Inc. service center. In order to ensure system specifications, the new modules need to be installed, and the complete unit calibrated, contact your nearest Keysight Technologies office to arrange the installation and calibration of new B1505A modules.

B1505A Specifications

Supported plug-In modules

The B1505A supports ten slots for plug-in modules.

Part number	Description	Slots occupied	Range of operation	Measure resolution
B1510A	High Power Source Monitor Unit (HPSMU)	2	-200 V to 200 V, -1 A to 1 A	2 μ V, 10 fA
B1511B	Medium Power Source Monitor Unit (MPSMU)	1	-100 V to 100 V, -100 mA to 100 mA	0.5 μ V, 10 fA
B1512A	High Current Source Monitor Unit (HCSMU)	2	-40 V to 40 V, -1 A to 1 A -20 V to 20 V, -20 A to 20 A (Pulse only)	200 nV, 10 pA
B1513C	High Voltage Source Monitor Unit (HVSMU)	2	-3000 V to 3000 V, -4 mA to 4 mA -1500 V to 1500 V, -8 mA to 8 mA	200 μ V, 10 fA
B1514A	Medium Current Source Monitor Unit (MCSMU)	1	-30 V to 30 V, -100 mA to 100 mA -30 V to 30 V, -1 A to 1 A (Pulse only)	200 nV, 10 pA
B1520A ¹	Multi Frequency Capacitance Measurement Unit (MFCMU)	1	1 kHz to 5 MHz	

1. N1300A-100 SMU CMU Unify Unit (SCUU) is not supported for the B1505A.

Specifications

Maximum module configuration	The total power consumption of all modules cannot exceed 84 W. Under this rule, the B1505A can contain any combination of the following SMUs: • Up to 4 dual-slot HPSMUs ¹ • Up to 10 single-slot MPSMUs • Up to 2 dual-slot HCSMUs ¹ • Up to 6 single-slot MCSMUs • Up to 5 dual-slot HVSMU In addition, up to 1 single-slot MFCMU can be installed per B1505A mainframe for any of the above-listed SMU configurations. The installation order of the modules is HPSMU, MPSMU, MFCMU, MCSMU, HCSMU, and HVSMU, starting from the bottom of the B1505A mainframe. Note 1. The total number of installed HPSMU and HCSMU modules cannot exceed 4.
Maximum voltage between Common and Ground	$\leq \pm 42$ V
Ground Unit (GNDU) specifications	The GNDU is furnished with the B1505A mainframe. • Output voltage: 0 V $\pm$ 100 μV • Maximum sink current: ± 4.2 A Output terminal/connection: • Triaxial connector, Kelvin (remote sensing)
GNDU supplemental characteristics	Load capacitance: 1 μF Cable resistance: • For $I_s \leq 1.6$ A: Force line $R < 1 \Omega$

- For $1.6\text{ A} < I_S \leq 2.0\text{ A}$: Force line $R < 0.7\ \Omega$
 - For $2.0\text{ A} < I_S \leq 4.2\text{ A}$: Force line $R < 0.35\ \Omega$
 - For all cases: Sense line $R \leq 10\ \Omega$
- Where I_S is the current being sunk by the GNDU.

Peripherals and interface

Data storage
SSD, DVD-R drive¹

Interfaces

GPIB, interlock, USB (USB 2.0, front 2, rear 2), LAN (1000BASE-T/100BASE-TX/10BASE-T), trigger in/out, digital I/O, VGA video output

Remote control capabilities

- FLEX commands (GPIB)
- EasyEXPERT group+ remote control function (LAN)

Trigger I/O

Only available using GPIB FLEX commands.

Trigger in/out synchronization pulses before and after setting and measuring DC voltage and current. Arbitrary trigger events can be masked or activated independently.

Furnished software

- EasyEXPERT group+
- MDM file converter

This tool can convert the EasyEXPERT group+ file (XTR/ZTR) to Keysight IC-CAP MDM file format.

The EasyEXPERT file of the following measurements performed in the classic mode is only supported:

- IV Sweep
- Multi-channel IV Sweep
- CV Sweep

- 4155/56 setup file converter tool

This tool can convert 4155 and 4156 measurement setup files (file extensions MES or DAT) into equivalent EXPERT group+ classic test mode setup files

¹. Mainframe with serial number MY64320101 or later is not equipped with DVD drive.

HPSMU Module Specifications

Voltage range, resolution, and accuracy (high-resolution ADC)

Voltage range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + mV)	Measure accuracy ¹ ± (% + mV)	Maximum current
±2 V	100 µV	2 µV	±(0.018 + 0.4)	±(0.01 + 0.14)	1 A
±20 V	1 mV	20 µV	±(0.018 + 3)	±(0.009 + 0.9)	1 A
±40 V	2 mV	40 µV	±(0.018 + 6)	±(0.01 + 1)	500 mA
±100 V	5 mV	100 µV	±(0.018 + 15)	±(0.012 + 2.5)	125 mA
±200 V	10 mV	200 µV	±(0.018 + 30)	±(0.014 + 2.8)	50 mA

1. ± (% of reading value + offset value in mV)

Current range, resolution, and accuracy (high-resolution ADC)

Current range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + A + A)	Measure accuracy ¹ ± (% + A + A)	Maximum voltage
±1 nA	50 fA	10 fA	±(0.1 + 3E-13 + Vo x 1E-15)	±(0.1 + 2E-13 + Vo x 1E-15)	200 V
±10 nA	500 fA	10 fA	±(0.1 + 3E-12 + Vo x 1E-14)	±(0.1 + 1E-12 + Vo x 1E-14)	200 V
±100 nA	5 pA	100 fA	±(0.05 + 3E-11 + Vo x 1E-13)	±(0.05 + 2E-11 + Vo x 1E-13)	200 V
±1 µA	50 pA	1 pA	±(0.05 + 3E-10 + Vo x 1E-12)	±(0.05 + 1E-10 + Vo x 1E-12)	200 V
±10 µA	500 pA	10 pA	±(0.05 + 3E-9 + Vo x 1E-11)	±(0.04 + 2E-9 + Vo x 1E-11)	200 V
±100 µA	5 nA	100 pA	±(0.035 + 15E-9 + Vo x 1E-10)	±(0.03 + 3E-9 + Vo x 1E-10)	200 V
±1 mA	50 nA	1 nA	±(0.04 + 15E-8 + Vo x 1E-9)	±(0.03 + 6E-8 + Vo x 1E-9)	200 V
±10 mA	500 nA	10 nA	±(0.04 + 15E-7 + Vo x 1E-8)	±(0.03 + 2E-7 + Vo x 1E-8)	200 V
±100 mA	5 µA	100 nA	±(0.045 + 15E-6 + Vo x 1E-7)	±(0.04 + 6E-6 + Vo x 1E-7)	200 V ²
±1 A	50 µA	1 µA	±(0.4 + 3E-4 + Vo x 1E-6)	±(0.4 + 15E-5 + Vo x 1E-6)	200 V ²

1. ± (% of reading value + fixed offset in A + proportional offset in A), Vo is the output voltage in V.)

2. 200 V (Io ≤ 50 mA), 100 V (50 mA < Io ≤ 125 mA), 40 V (125 mA < Io ≤ 500 mA), 20 V (500 mA < Io ≤ 1 A), Io is the output current in A.

Voltage range, resolution, and accuracy (high-speed ADC)

Voltage range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + mV)	Measure accuracy ¹ ± (% + mV)	Maximum current
±2 V	100 µV	100 µV	±(0.018 + 0.4)	±(0.01 + 0.7)	1 A
±20 V	1 mV	1 mV	±(0.018 + 3)	±(0.01 + 4)	1 A
±40 V	2 mV	2 mV	±(0.018 + 6)	±(0.015 + 8)	500 mA
±100 V	5 mV	5 mV	±(0.018 + 15)	±(0.02 + 20)	125 mA
±200 V	10 mV	10 mV	±(0.018 + 30)	±(0.035 + 40)	50 mA

1. ± (% of reading value + offset value in mV). Averaging is 128 samples in 1 PLC.

Current range, resolution, and accuracy (high-speed ADC)

Current range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + A + A)	Measure accuracy ¹ ± (% + A + A)	Maximum voltage
±1 nA	50 fA	50 fA	±(0.1 + 3E-13 + Vo x 1E-15)	±(0.25 + 3E-13 + Vo x 1E-15)	200 V
±10 nA	500 fA	500 fA	±(0.1 + 3E-12 + Vo x 1E-14)	±(0.25 + 2E-12 + Vo x 1E-14)	200 V
±100 nA	5 pA	5 pA	±(0.05 + 3E-11 + Vo x 1E-13)	±(0.1 + 2E-11 + Vo x 1E-13)	200 V
±1 µA	50 pA	50 pA	±(0.05 + 3E-10 + Vo x 1E-12)	±(0.1 + 2E-10 + Vo x 1E-12)	200 V
±10 µA	500 pA	500 pA	±(0.05 + 3E-9 + Vo x 1E-11)	±(0.05 + 2E-9 + Vo x 1E-11)	200 V
±100 µA	5 nA	5 nA	±(0.035 + 15E-9 + Vo x 1E-10)	±(0.05 + 2E-8 + Vo x 1E-10)	200 V
±1 mA	50 nA	50 nA	±(0.04 + 15E-8 + Vo x 1E-9)	±(0.04 + 2E-7 + Vo x 1E-9)	200 V
±10 mA	500 nA	500 nA	±(0.04 + 15E-7 + Vo x 1E-8)	±(0.04 + 2E-6 + Vo x 1E-8)	200 V
±100 mA	5 µA	5 µA	±(0.045 + 15E-6 + Vo x 1E-7)	±(0.1 + 2E-5 + Vo x 1E-7)	200 V ²
±1 A	50 µA	50 µA	±(0.4 + 3E-4 + Vo x 1E-6)	±(0.5 + 3E-4 + Vo x 1E-6)	200 V ²

1. ±(% of reading value + fixed offset in A + proportional offset in A), Vo is the output voltage in V.)

2. 200 V (Io ≤ 50 mA), 100 V (50 mA < Io ≤ 125 mA), 40 V (125 mA < Io ≤ 500 mA), 20 V (500 mA < Io ≤ 1 A), Io is the output current in A.

Power consumption

Voltage source mode

Voltage range	Power
2 V	$20 \times I_c$ (W)
20 V	$20 \times I_c$ (W)
40 V	$40 \times I_c$ (W)
100 V	$100 \times I_c$ (W)
200 V	$200 \times I_c$ (W)

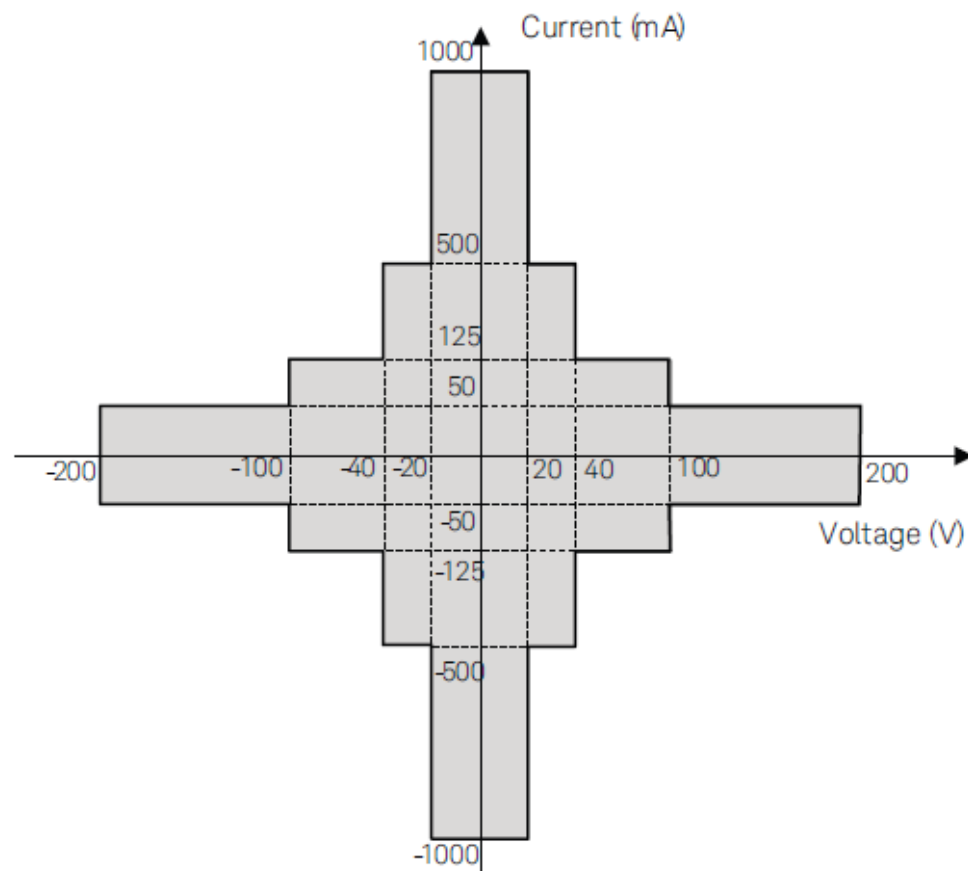
Where I_c is the current compliance setting.

Current source mode

Voltage compliance	Power
$V_c \leq 20$	$20 \times I_o$ (W)
$20 < V_c \leq 40$	$40 \times I_o$ (W)
$40 < V_c \leq 100$	$100 \times I_o$ (W)
$100 < V_c \leq 200$	$200 \times I_o$ (W)

Where V_c is the voltage compliance setting, and I_o is the output current.

HPSMU measurement and output range



MPSMU Module Specifications

Voltage range, resolution, and accuracy (high-resolution ADC)

Voltage range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + mV)	Measure accuracy ¹ ± (% + mV)	Maximum current
±0.5 V	25 µV	0.5 µV	±(0.018 + 0.15)	±(0.01 + 0.12)	100 mA
±2 V	100 µV	2 µV	±(0.018 + 0.4)	±(0.01 + 0.14)	100 mA
±5 V	250 µV	5 µV	±(0.018 + 0.75)	±(0.009 + 0.25)	100 mA
±20 V	1 mV	20 µV	±(0.018 + 3)	±(0.009 + 0.9)	100 mA
±40 V	2 mV	40 µV	±(0.018 + 6)	±(0.01 + 1)	²
±100 V	5 mV	100 µV	±(0.018 + 15)	±(0.012 + 2.5)	²

1. ± (% of reading value + offset value in mV)

2. 100 mA ($V_o \leq 20$ V), 50 mA (20 V < $V_o \leq 40$ V), 20 mA (40 V < $V_o \leq 100$ V), V_o is the output voltage in V.

Current range, resolution, and accuracy (high-resolution ADC)

Current range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + A + A)	Measure accuracy ¹ ± (% + A + A)	Maximum voltage
±1 nA	50 fA	10 fA	±(0.1 + 3E-13 + $V_o \times 1E-15$)	±(0.1 + 2E-13 + $V_o \times 1E-15$)	100 V
±10 nA	500 fA	10 fA	±(0.1 + 3E-12 + $V_o \times 1E-14$)	±(0.1 + 1E-12 + $V_o \times 1E-14$)	100 V
±100 nA	5 pA	100 fA	±(0.05 + 3E-11 + $V_o \times 1E-13$)	±(0.05 + 2E-11 + $V_o \times 1E-13$)	100 V
±1 µA	50 pA	1 pA	±(0.05 + 3E-10 + $V_o \times 1E-12$)	±(0.05 + 1E-10 + $V_o \times 1E-12$)	100 V
±10 µA	500 pA	10 pA	±(0.05 + 3E-9 + $V_o \times 1E-11$)	±(0.04 + 2E-9 + $V_o \times 1E-11$)	100 V
±100 µA	5 nA	100 pA	±(0.035 + 15E-9 + $V_o \times 1E-10$)	±(0.03 + 3E-9 + $V_o \times 1E-10$)	100 V
±1 mA	50 nA	1 nA	±(0.04 + 15E-8 + $V_o \times 1E-9$)	±(0.03 + 6E-8 + $V_o \times 1E-9$)	100 V
±10 mA	500 nA	10 nA	±(0.04 + 15E-7 + $V_o \times 1E-8$)	±(0.03 + 2E-7 + $V_o \times 1E-8$)	100 V
±100 mA	5 µA	100 nA	±(0.045 + 15E-6 + $V_o \times 1E-7$)	±(0.04 + 6E-6 + $V_o \times 1E-7$)	²

1. ± (% of reading value + fixed offset in A + proportional offset in A), V_o is the output voltage in V.)

2. 100 V ($I_o \leq 20$ mA), 40 V (20 mA < $I_o \leq 50$ mA), 20 V (50 mA < $I_o \leq 100$ mA), I_o is the output current in A.

Voltage range, resolution, and accuracy (high-speed ADC)

Voltage range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + mV)	Measure accuracy ¹ ± (% + mV)	Maximum current
±0.5 V	25 µV	25 µV	±(0.018 + 0.15)	±(0.01 + 0.25)	100 mA
±2 V	100 µV	100 µV	±(0.018 + 0.4)	±(0.01 + 0.7)	100 mA
±5 V	250 µV	250 µV	±(0.018 + 0.75)	±(0.01 + 2)	100 mA
±20 V	1 mV	1 mV	±(0.018 + 3)	±(0.01 + 4)	100 mA
±40 V	2 mV	2 mV	±(0.018 + 6)	±(0.015 + 8)	²
±100 V	5 mV	5 mV	±(0.018 + 15)	±(0.02 + 20)	²

1. ±(% of reading value + offset value in mV). Averaging is 128 samples in 1 PLC.

2. 100 mA ($V_o \leq 20$ V), 50 mA (20 V < $V_o \leq 40$ V), 20 mA (40 V < $V_o \leq 100$ V), V_o is the output voltage in V.

Current range, resolution, and accuracy (high-speed ADC)

Current range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + A + A)	Measure accuracy ¹ ± (% + A + A)	Maximum voltage
±1 nA	50 fA	50 fA	±(0.1 + 3E-13 + $V_o \times 1E-15$)	±(0.25 + 3E-13 + $V_o \times 1E-15$)	100 V
±10 nA	500 fA	500 fA	±(0.1 + 3E-12 + $V_o \times 1E-14$)	±(0.25 + 2E-12 + $V_o \times 1E-14$)	100 V
±100 nA	5 pA	5 pA	±(0.05 + 3E-11 + $V_o \times 1E-13$)	±(0.1 + 2E-11 + $V_o \times 1E-13$)	100 V
±1 µA	50 pA	50 pA	±(0.05 + 3E-10 + $V_o \times 1E-12$)	±(0.1 + 2E-10 + $V_o \times 1E-12$)	100 V
±10 µA	500 pA	500 pA	±(0.05 + 3E-9 + $V_o \times 1E-11$)	±(0.05 + 2E-9 + $V_o \times 1E-11$)	100 V
±100 µA	5 nA	5 nA	±(0.035 + 15E-9 + $V_o \times 1E-10$)	±(0.05 + 2E-8 + $V_o \times 1E-10$)	100 V
±1 mA	50 nA	50 nA	±(0.04 + 15E-8 + $V_o \times 1E-9$)	±(0.04 + 2E-7 + $V_o \times 1E-9$)	100 V
±10 mA	500 nA	500 nA	±(0.04 + 15E-7 + $V_o \times 1E-8$)	±(0.04 + 2E-6 + $V_o \times 1E-8$)	100 V
±100 mA	5 µA	5 µA	±(0.045 + 15E-6 + $V_o \times 1E-7$)	±(0.1 + 2E-5 + $V_o \times 1E-7$)	²

1. ±(% of reading value + fixed offset in A + proportional offset in A), V_o is the output voltage in V.)

2. 100 V ($I_o \leq 20$ mA), 40 V (20 mA < $I_o \leq 50$ mA), 20 V (50 mA < $I_o \leq 100$ mA), I_o is the output current in A.

Power consumption

Voltage source mode

Voltage range	Power
0.5 V	$20 \times I_c$ (W)
2 V	$20 \times I_c$ (W)
5 V	$20 \times I_c$ (W)
20 V	$20 \times I_c$ (W)
40 V	$40 \times I_c$ (W)
100 V	$100 \times I_c$ (W)

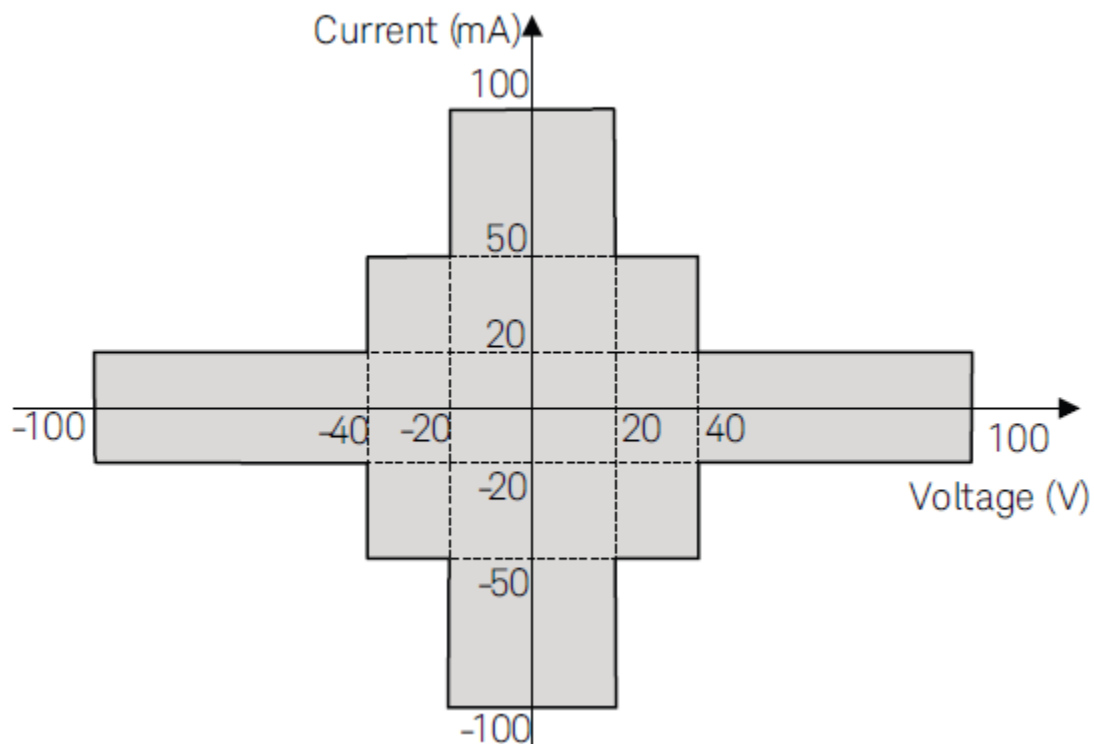
Where I_c is the current compliance setting.

Current source mode

Voltage compliance	Power
$V_c \leq 20$	$20 \times I_o$ (W)
$20 < V_c \leq 40$	$40 \times I_o$ (W)
$40 < V_c \leq 100$	$100 \times I_o$ (W)

Where V_c is the voltage compliance setting, and I_o is the output current.

MPSMU measurement and output range



HCSMU Module Specifications

Voltage range, resolution, and accuracy

Voltage range	Force resolution	Measure resolution	Force accuracy ¹ (% + mV + mV)	Measure accuracy ¹ (% + mV + mV)	Maximum current
±0.2 V	200 nV	200 nV	$\pm(0.06 + 0.14 + I_o \times 0.05)$	$\pm(0.06 + 0.14 + I_o \times 0.05)$	20 A
±2 V	2 µV	2 µV	$\pm(0.06 + 0.6 + I_o \times 0.5)$	$\pm(0.06 + 0.6 + I_o \times 0.5)$	20 A
±20 V	20 µV	20 µV	$\pm(0.06 + 3 + I_o \times 5)$	$\pm(0.06 + 3 + I_o \times 5)$	20 A
±40 V	40 µV	40 µV	$\pm(0.06 + 3 + I_o \times 10)$	$\pm(0.06 + 3 + I_o \times 10)$	1 A

1. $\pm(\%$ of reading value + fixed offset in mV + proportional offset in mV). Note: I_o is the output current in A.

Current range, resolution, and accuracy

Current range	Force resolution	Measure resolution	Force accuracy ¹ (% + A + A)	Measure accuracy ¹ (% + A + A)	Maximum voltage
±10 µA	10 pA	10 pA	$\pm(0.06 + 2E-9 + V_o \times 1E-10)$	$\pm(0.06 + 2E-9 + V_o \times 1E-10)$	40 V
±100 µA	100 pA	100 pA	$\pm(0.06 + 2E-8 + V_o \times 1E-9)$	$\pm(0.06 + 2E-8 + V_o \times 1E-9)$	40 V
±1 mA	1 nA	1 nA	$\pm(0.06 + 2E-7 + V_o \times 1E-8)$	$\pm(0.06 + 2E-7 + V_o \times 1E-8)$	40 V
±10 mA	10 nA	10 nA	$\pm(0.06 + 2E-6 + V_o \times 1E-7)$	$\pm(0.06 + 2E-6 + V_o \times 1E-7)$	40 V
±100 mA	100 nA	100 nA	$\pm(0.06 + 2E-5 + V_o \times 1E-6)$	$\pm(0.06 + 2E-5 + V_o \times 1E-6)$	40 V
±1 A	1 µA	1 µA	$\pm(0.4 + 2E-4 + V_o \times 1E-5)$	$\pm(0.4 + 2E-4 + V_o \times 1E-5)$	40 V
±20 A ²	20 µA	20 µA	$\pm(0.4 + 2E-3 + V_o \times 1E-4)$	$\pm(0.4 + 2E-3 + V_o \times 1E-4)$	20 V

1. $\pm(\%$ of reading value + fixed offset in A + proportional offset in A), V_o is the output voltage in V.

2. Pulse mode only. The maximum value of the base current during pulsing is ±100 mA.

Current range expansion

If two HCSMUs are combined using the Dual HCSMU combination adapter or the Dual HCSMU Kelvin combination adapter, then the maximum current ranges are 40 A (Pulsed) and 2 A (DC).

Power consumption

Voltage source mode

Voltage range	Power
0.2 V	$40 \times I_c$ (W)
2 V	$40 \times I_c$ (W)
40 V	$40 \times I_c$ (W)

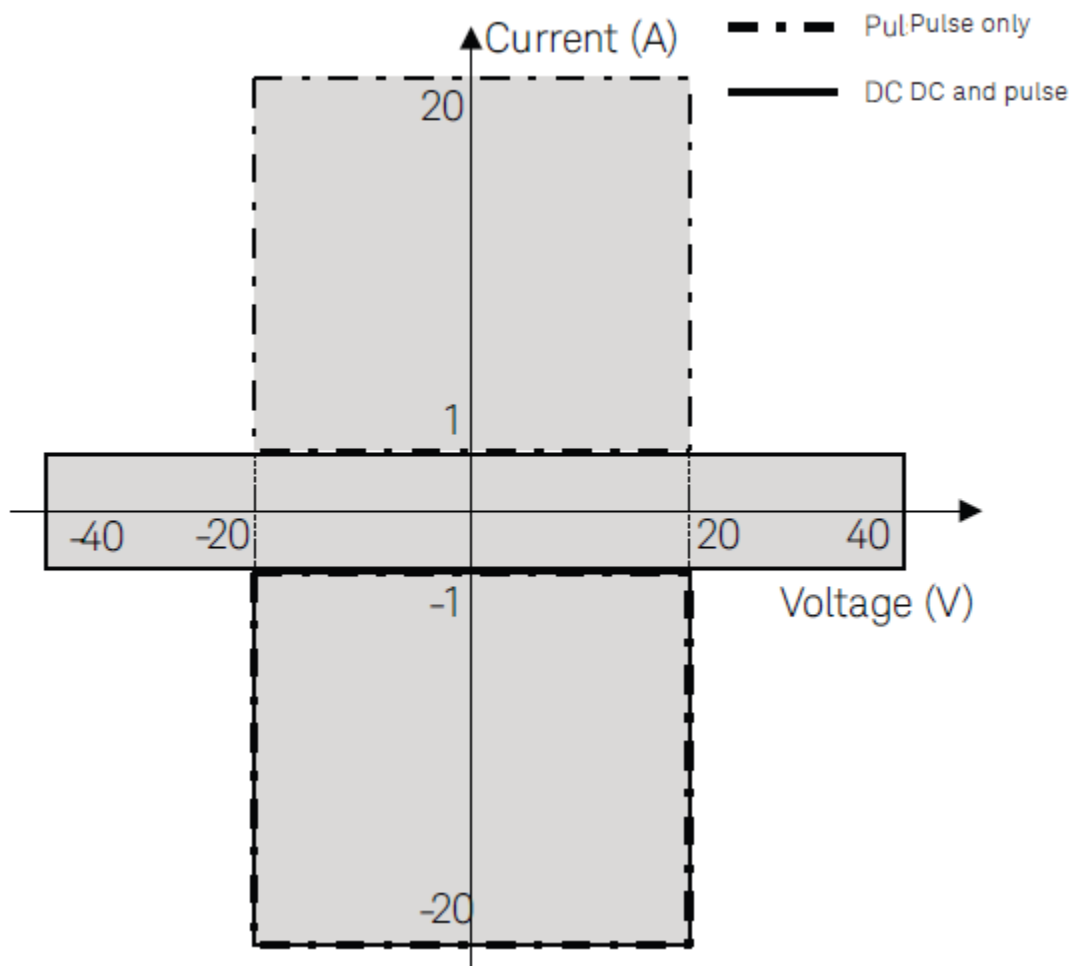
Where I_c is the current compliance setting.
For pulse current, $I_c = (\text{duty}) \times I_{\text{pulse}}$

Current source mode

Voltage compliance	Power
$V_c \leq 0.2$	$40 \times I_o$ (W)
$0.2 < V_c \leq 2$	$40 \times I_o$ (W)
$2 < V_c \leq 40$	$40 \times I_o$ (W)

Where V_c is the voltage compliance setting, and I_o is the output current.
For pulse current, $I_o = (\text{duty}) \times I_{\text{pulse}}$

HCSMU measurement and output range



HVSMU Module Specifications

Voltage range, resolution, and accuracy

Voltage range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + mV)	Measure accuracy ¹ ± (% + mV)	Maximum current
±200 V	200 µV	200 µV	±(0.03 + 40)	±(0.03 + 40)	8 mA
±500 V	500 µV	500 µV	±(0.03 + 100)	±(0.03 + 100)	8 mA
±1500 V	1.5 mV	1.5 mV	±(0.03 + 300)	±(0.03 + 300)	8 mA
±3000 V	3 mV	3 mV	±(0.03 + 600)	±(0.03 + 600)	4 mA

1. ±(% of reading value + offset voltage in V)

Current range, resolution, and accuracy

Current range	Force resolution	Measure resolution	Force accuracy ¹ ± (% + A + A)	Measure accuracy ¹ ± (% + A + A)	Maximum voltage	Minimum set current ²
±1 nA	10 fA	10 fA	±(0.1 + 6E-13 + Vo x 1E-15)	±(0.1 + 6E-13 + Vo x 1E-15)	3000 V	1pA
±10 nA	100 fA	100 fA	±(0.1 + 25E-13 + Vo x 1E-15)	±(0.1 + 25E-13 + Vo x 1E-15)	3000 V	1pA
±100 nA	100 fA	100 fA	±(0.05 + 25E-12 + Vo x 1E-13)	±(0.05 + 25E-12 + Vo x 1E-13)	3000 V	100 pA
±1 µA	1 pA	1 pA	±(0.05 + 1E-10 + Vo x 1E-13)	±(0.05 + 1E-10 + Vo x 1E-13)	3000 V	100 pA
±10 µA	10 pA	10 pA	±(0.04 + 2E-9 + Vo x 1E-11)	±(0.04 + 2E-9 + Vo x 1E-11)	3000 V	10 nA
±100 µA	100 pA	100 pA	±(0.03 + 3E-9 + Vo x 1E-11)	±(0.03 + 3E-9 + Vo x 1E-11)	3000 V	10 nA
±1 mA	1 nA	1 nA	±(0.03 + 6E-8 + Vo x 1E-10)	±(0.03 + 6E-8 + Vo x 1E-10)	3000 V	100 nA
±10 mA	10 nA	10 nA	±(0.03 + 2E-7 + Vo x 1E-9)	±(0.03 + 2E-7 + Vo x 1E-9)	1500 V	1 µA

1. ±(% of reading value + fixed offset in A + proportional offset in A), Vo is the output voltage in V.)

2. Output current needs to be set more than the current shown in the table.

Power consumption

Voltage source mode

Current compliance	Power
I c ≤ 4 m	3000 x I c + 12 (W) ¹
4 m < I c ≤ 8 m	1500 x I c + 12 (W) ¹

Where I c is the current compliance setting.

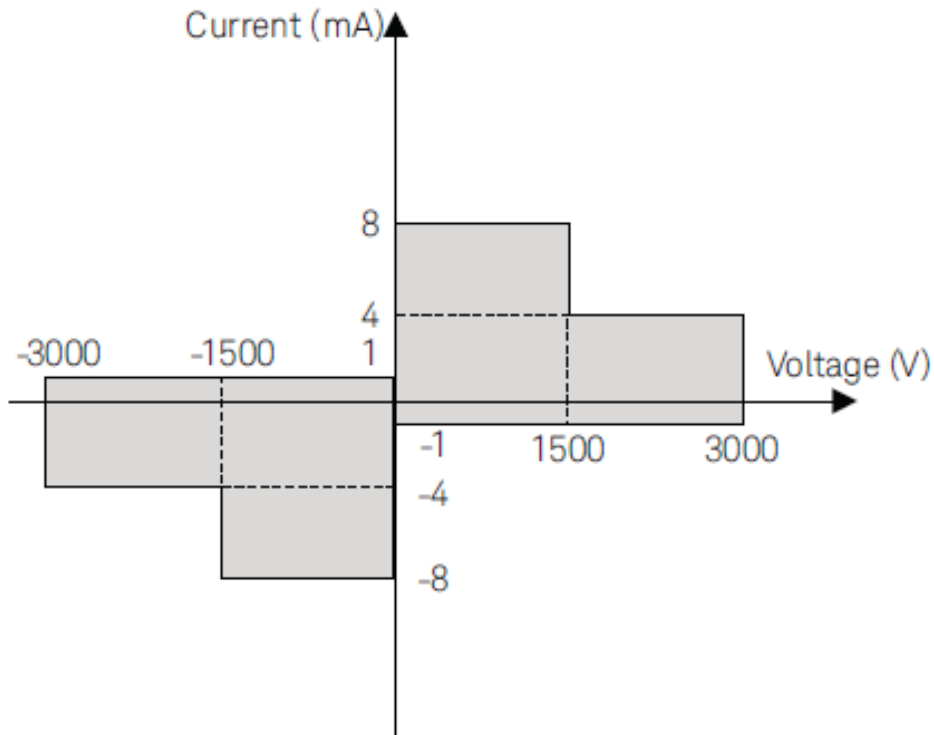
Current source mode

Voltage compliance	Power
V c ≤ 1500	1500 x I o (W) + 12 ¹
1500 < V c ≤ 3000	3000 x I o (W) + 12 ¹

Where V c is the voltage compliance setting, and I o is the output current.

1. The "+ 12" factor does not apply to the first installed HVSMU; it only applies to the second thru fifth installed HVSMUs.

HVSMU measurement and output range



HVSMU has 3 output range settings, which are “0 to +3 kV”, “-1500 V to +1500 V”, and “0 to -3 kV”. If more than one HVSMU is installed in the B1505A, all of the HVSMUs must use the same output range setting.

MCSMU Module Specifications

Voltage range, resolution, and accuracy

Voltage range	Force resolution	Measure resolution	Force accuracy ¹ $\pm$ (% + mV)	Measure accuracy ¹ (% + mV)	Maximum current
± 0.2 V	200 nV	200 nV	$\pm(0.06 + 0.14)$	$\pm(0.06 + 0.14)$	1 A
± 2 V	2 μ V	2 μ V	$\pm(0.06 + 0.6)$	$\pm(0.06 + 0.6)$	1 A
± 20 V	20 μ V	20 μ V	$\pm(0.06 + 3)$	$\pm(0.06 + 3)$	1 A
± 40 V ²	40 μ V	40 μ V	$\pm(0.06 + 3)$	$\pm(0.06 + 3)$	1 A

1. $\pm$ (% of reading value + fixed offset in mV).

2. Maximum output voltage is 30 V.

Current range, resolution, and accuracy

Current range	Force resolution	Measure resolution	Force accuracy ¹ (% + A + A)	Measure accuracy ¹ (% + A + A)	Maximum voltage
± 10 μ A	10 pA	10 pA	$\pm(0.06 + 2E-9 + V_o \times 1E-10)$	$\pm(0.06 + 2E-9 + V_o \times 1E-10)$	30 V
± 100 μ A	100 pA	100 pA	$\pm(0.06 + 2E-8 + V_o \times 1E-9)$	$\pm(0.06 + 2E-8 + V_o \times 1E-9)$	30 V
± 1 mA	1 nA	1 nA	$\pm(0.06 + 2E-7 + V_o \times 1E-8)$	$\pm(0.06 + 2E-7 + V_o \times 1E-8)$	30 V
± 10 mA	10 nA	10 nA	$\pm(0.06 + 2E-6 + V_o \times 1E-7)$	$\pm(0.06 + 2E-6 + V_o \times 1E-7)$	30 V
± 100 mA	100 nA	100 nA	$\pm(0.06 + 2E-5 + V_o \times 1E-6)$	$\pm(0.06 + 2E-5 + V_o \times 1E-6)$	30 V
± 1 A ²	1 μ A	1 μ A	$\pm(0.4 + 2E-4 + V_o \times 1E-5)$	$\pm(0.4 + 2E-4 + V_o \times 1E-5)$	30 V

1. $\pm$ (% of reading value + fixed offset in A + proportional offset in A), V_o is the output voltage in V.

2. Pulse mode only. The maximum value of the base current during pulsing is ± 50 mA.

Power consumption

Voltage source mode

Voltage range	Power
0.2 V	40 x I_c (W)
2 V	40 x I_c (W)
40 V	40 x I_c (W)

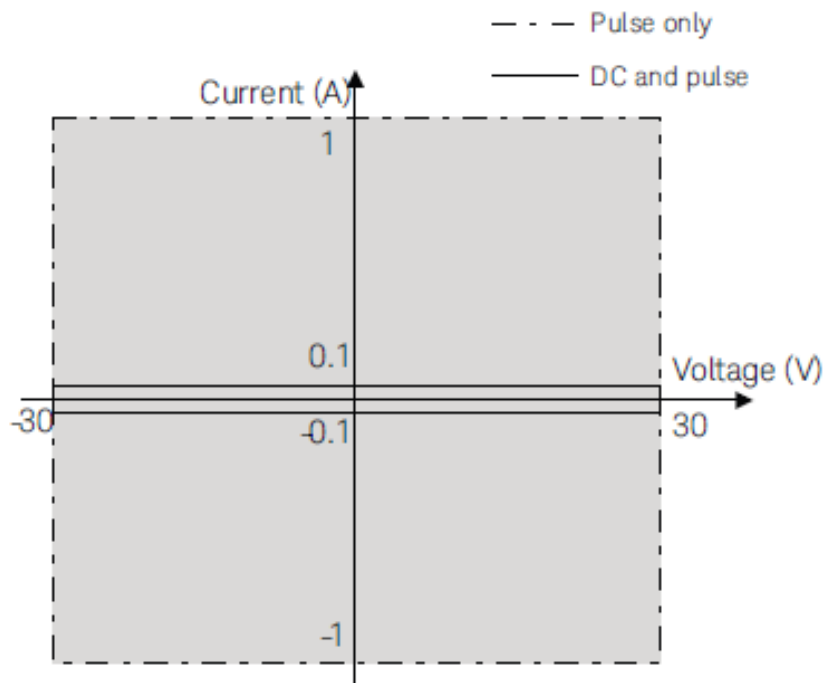
Where I_c is the current compliance setting.

Current source mode

Voltage compliance	Power
$V_c \leq 0.2$	40 x I_o (W)
$0.2 < V_c \leq 2$	40 x I_o (W)
$2 < V_c \leq 40$	40 x I_o (W)

Where V_c is the voltage compliance setting, and I_o is the output current.

MCSMU measurement and output range



Specifications

SMU source measurement mode	For HPSMU and MPSMU: VFIM, IFVM
	For HCSMU, MCSMU and HVSMU: VFIM, VFVM, IFVM, IFIM
Output terminal/connection	For HPSMU and MPSMU: • Dual triaxial connector, • Kelvin (remote sensing) For HCSMU: • Triaxial connector (for sense) and coaxial connector (for force) • Kelvin (remote sensing) For MCSMU: • Dual triaxial connector, Kelvin (remote sensing) For HVSMU: • High voltage triaxial connector, non-Kelvin
Voltage/current compliance (limiting)	The SMU can limit output voltage or current to prevent damaging the device under test. Voltage: • 0 V to ± 200 V (HPSMU) • 0 V to ± 100 V (MPSMU) • 0 V to ± 40 V (HCSMU) • 0 V to ± 30 V (MCSMU) • 0 V to ± 3000 V (HVSMU) Current: • ± 1 pA to ± 1 A (HPSMU) • ± 1 pA to ± 100 mA (MPSMU) • ± 10 nA to ± 20 A (HCSMU) • ± 10 nA to ± 1 A (MCSMU) • ± 1 pA to ± 8 mA (HVSMU) Compliance accuracy: • Same as the current or voltage set accuracy.
Power compliance	For HPSMU: • Power: 0.001 W to 20 W • Resolution: 0.001 W For MPSMU: • Power: 0.001 W to 2 W • Resolution: 0.001 W For HCSMU: • Power: 0.001 W to 40 W (DC) • 0.001 W to 400 W (Pulse) • Resolution: 0.001 W For MCSMU: • Power: 0.001 W to 3 W (DC) • 0.001 W to 30 W (Pulse) • Resolution: 0.001 W For HVSMU: • No power compliance
SMU pulse measurement	Pulse width, period, and delay: For HPSMU and MPSMU: • Pulse width: 500 μs to 2 s • Pulse width resolution: 100 μs

- Pulse period: 5 ms to 5 s
 - $\text{Period} \geq \text{delay} + \text{width} + 2 \text{ ms}$ (when $\text{delay} + \text{width} \leq 100 \text{ ms}$)
 - $\text{Period} \geq \text{delay} + \text{width} + 10 \text{ ms}$ (when $\text{delay} + \text{width} > 100 \text{ ms}$)
 - Pulse period resolution: 100 μs
 - Pulse delay: 0 s

For HCSMU:

- Pulse width:
 - 50 μs to 1 ms (20 A range)
 - 50 μs to 2 s (10 μA to 1 A range)
- Pulse width resolution: 2 μs
- Pulse period: 5 ms to 5 s
- Pulse period resolution: 100 μs
- Pulse duty:
 - For 20 A range: $\leq 1\%$
 - For 10 μA to 1 A range
 - $\text{Period} \geq \text{delay} + \text{width} + 2 \text{ ms}$ (when $\text{delay} + \text{width} \leq 100 \text{ ms}$)
 - $\text{Period} \geq \text{delay} + \text{width} + 10 \text{ ms}$ (when $\text{delay} + \text{width} > 100 \text{ ms}$)
 - Pulse delay: 0 to (Period – width)

For MCSMU:

- Pulse width:
 - 10 μs to 100 ms (1 A range)
 - 10 μs to 2 s (10 μA to 100 mA range)
 - Pulse width resolution: 2 μs
 - Pulse period: 5 ms to 5 s
 - Pulse period resolution: 100 μs
 - Pulse duty:
 - For 1 A range: $\leq 5\%$
 - For 10 μA to 100 mA range
 - $\text{Period} \geq \text{delay} + \text{width} + 2 \text{ ms}$ (when $\text{delay} + \text{width} \leq 100 \text{ ms}$)
 - $\text{Period} \geq \text{delay} + \text{width} + 10 \text{ ms}$ (when $\text{delay} + \text{width} > 100 \text{ ms}$)
 - Pulse delay: 0 to (Period – width)

For HVSMU:

- Pulse width: 500 μs to 2 s
 - Pulse width resolution: 2 μs
 - Pulse period: 5 ms to 5 s
 - $\text{Period} \geq \text{delay} + \text{width} + 2 \text{ ms}$ (when $\text{delay} + \text{width} \leq 100 \text{ ms}$)
 - $\text{Period} \geq \text{delay} + \text{width} + 10 \text{ ms}$ (when $\text{delay} + \text{width} > 100 \text{ ms}$)
 - Pulse period resolution: 100 μs
 - Pulse delay: 0 to (Period – width)
 - Pulse output limitation:
 - When the pulse voltage is more than 1500 V, the peak and base of the pulse should be the same polarities.
 - Pulse measurement delay:
 - 2 μs to (Period – pulse measurement time – 2 m) s, 2 μs resolution
-

Supplemental Characteristics

Current compliance setting accuracy (for opposite polarity)	For HPSMU and MPSMU: - For 1 pA to 10 nA ranges: - V/I setting accuracy $\pm 12\%$ of range - For 100 nA to 1 A ranges: - V/I setting accuracy $\pm 2.5\%$ of range For HCSMU and MCSMU: - For 10 μA to 1 A ranges: - V/I setting accuracy $\pm 2.5\%$ of range - For 20 A range (HCSMU): - V/I setting accuracy $\pm 0.6\%$ of range For HVSMU: - For 1 nA to 10 nA ranges: - V/I setting accuracy $\pm 12\%$ of range - For 100 nA to 10 mA ranges: - V/I setting accuracy $\pm 2.5\%$ of range
SMU pulse setting accuracy (fixed measurement range)	For HPSMU and MPSMU: - Width: $\pm 0.5\% \pm 50 \mu$s - Period: $\pm 0.5\% \pm 100 \mu$s For HCSMU and MCSMU: - Width: $\pm 0.1\% \pm 2 \mu$s - Period: $\pm 0.1\% \pm 100 \mu$s For HVSMU: - Width: $\pm 0.1\% \pm 2 \mu$s - Period: $\pm 0.5\% \pm 100 \mu$s
Minimum pulse measurement time	16 μs (HPSMU and MPSMU) 2 μs (HCSMU and MCSMU) 6 μs (HVSMU)
Voltage source output resistance	(Force line, non-Kelvin connection) 0.2 Ω (HPSMU) 0.3 Ω (MPSMU) 3 Ω (HVSMU, at 10 mA range)
Voltage measurement input resistance	$\geq 10^{13} \Omega$ (HPSMU, MPSMU) $\geq 10^9 \Omega$ (HCSMU, MCSMU, ≤ 1 A), 80 kΩ (HCSMU, 20 A) $\geq 10^{12} \Omega$ (HVSMU)
Current source output resistance	$\geq 10^{13} \Omega$ (HPSMU, MPSMU) $\geq 10^9 \Omega$ (HCSMU, MCSMU, ≤ 1 A), 80 kΩ (HCSMU, 20 A) $\geq 10^{12} \Omega$ (HVSMU, at 10 nA range)
Maximum allowable cable resistance	(Kelvin connection) For HPSMU and MPSMU: - Sense: 10 Ω - Force: 10 Ω (≤ 100 mA), 1.5 Ω (>100 mA) For HCSMU: - Sense: 10 Ω - Force: 0.6 Ω (with Low Force) For MCSMU: - Sense: 10 Ω - Force: 1 Ω (with Low Force)

Maximum allowable inductance	For HCSMU and MCSMU: • Force 3 μH ◦ (with Low Force (shield))
Maximum load capacitance	For HPSMU and MPSMU: • 1 pA to 10 nA ranges: 1000 pF • 100 nA to 10 mA ranges: 10 nF • 100 mA and 1 A ranges: 100 μF For HCSMU: • 10 μA to 10 mA ranges: 12 nF • 100 mA to 20 A ranges: 100 μF For MCSMU: • 10 μA to 10 mA range : 12 nF • 100 mA to 1 A range : 100 μF For HVSMU: • 1 nA to 1 μA ranges: 1000 pF • 10 μA to 10 mA ranges: 10 nF
Maximum guard capacitance	• 900 pF (HPSMU and MPSMU) • 1500 pF (HVSMU)
Maximum shield capacitance	• 5000 pF (HPSMU, MPSMU and HVSMU)
Noise characteristics	For HPSMU, MPSMU and HVSMU (Filter ON for HPSMU and MPSMU.) • Voltage source: ◦ 0.01% of V range (rms.) • Current source: ◦ 0.1% of I range (rms.) For HCSMU • Voltage/Current source: ◦ 100 mV (0 to peak) max For MCSMU • Voltage / Current source: ◦ 200 mV (0 to peak) max
Overshoot	(Filter ON for all SMUs) For HPSMU and MPSMU • Voltage source: 0.03% of V range • Current source: 1% of I range For HCSMU and MCSMU (filter ON) • Voltage/Current source: ◦ 10% of range For HVSMU • Voltage source: 1 V (resistive load) • Current source: 1% of I range
Range switching transient noise	For HPSMU and MPSMU (filter ON): • Voltage ranging: 250 mV • Current ranging: 70 mV For HCSMU and MCSMU: • 10 μA to 1 A ranges: ◦ Voltage ranging: 250 mV ◦ Current ranging: 70 mV • 20 A ranges: ◦ Voltage ranging: 5 V max For HVSMU: • Voltage ranging: 300 mV • Current ranging: 300 mV

Maximum guard offset voltage	• ± 1 mV (HPSMU) • ± 3 mV (MPSMU) • ± 5 mV (HVSMU)
Maximum slew rate	• 0.2 V/μs (HPSMU and MPSMU) • 1 V/μs (HCSMU and MCSMU) • 0.4 V/μs (HVSMU)
Output settling time	For HVSMU: • Output settling time: 500 μs To reach 0.01% of settling value. Conditions: • 100 V step, 8 mA compliance • 1000 pF load capacitance

MFCMU (multi-frequency capacitance measurement unit) module specifications

Specifications

Measurement functions	Measurement parameters: - Cp-G, Cp-D, Cp-Q, Cp-Rp, Cs-Rs, Cs-D, Cs-Q, Lp-G, Lp-D, Lp-Q, Lp-Rp, Ls-Rs, Ls-D, Ls-Q, R-X, G-B, Z-θ, Y-θ Ranging: - Auto and fixed Measurement terminal: - Four-terminal pair configuration, four BNC (female) connectors Cable length: 1.5 m or 3 m, automatic identification of accessories																				
Test signal	Frequency: - Range: 1 kHz to 5 MHz - Resolution: 1 mHz (minimum) - Accuracy: $\pm 0.008\%$ Output signal level: - Range: 10 mVrms to 250 mVrms - Resolution: 1 mVrms - Accuracy: $\pm(10.0\% + 1 \text{ mVrms})$ at the measurement port of the MFCMU $\pm(15.0\% + 1 \text{ mVrms})$ at the measurement port of MFCMU cable (1.5 m or 3 m) Output impedance: 50 Ω, typical Signal level monitor: - Range: 10 mVrms to 250 mVrms - Accuracy: $\pm(10.0\% \text{ of reading} + 1 \text{ mVrms})$ at the measurement port of the MFCMU $\pm(15.0\% + 1 \text{ mVrms})$ at the measurement port of MFCMU cable (1.5 m or 3 m)																				
DC bias function	DC bias: - Range: 0 to $\pm 25 \text{ V}$ - Resolution: 1 mV - Accuracy: $\pm(0.5\% + 5.0 \text{ mV})$ at the measurement port or the MFCMU or the MFCMU cable (1.5 m/3 m)																				
Maximum DC bias current (Supplemental characteristics)	<table> <tr> <th>Impedance measurement range</th><th>Maximum DC bias current</th></tr> <tr> <td>50 Ω</td><td>10 mA</td></tr> <tr> <td>100 Ω</td><td>10 mA</td></tr> <tr> <td>300 Ω</td><td>10 mA</td></tr> <tr> <td>1 kΩ</td><td>1 mA</td></tr> <tr> <td>3 kΩ</td><td>1 mA</td></tr> <tr> <td>10 kΩ</td><td>100 μA</td></tr> <tr> <td>30 kΩ</td><td>100 μA</td></tr> <tr> <td>100 kΩ</td><td>10 μA</td></tr> <tr> <td>300 kΩ</td><td>10 μA</td></tr> </table> Output impedance: 50 Ω, typical DC bias monitor: Range: 0 to $\pm 25 \text{ V}$ Accuracy (open load): $\pm(0.2\% \text{ of reading} + 10.0 \text{ mV})$ at the measurement port or the MFCMU cable (1.5 m/3 m)	Impedance measurement range	Maximum DC bias current	50 Ω	10 mA	100 Ω	10 mA	300 Ω	10 mA	1 k Ω	1 mA	3 k Ω	1 mA	10 k Ω	100 μA	30 k Ω	100 μA	100 k Ω	10 μA	300 k Ω	10 μA
Impedance measurement range	Maximum DC bias current																				
50 Ω	10 mA																				
100 Ω	10 mA																				
300 Ω	10 mA																				
1 k Ω	1 mA																				
3 k Ω	1 mA																				
10 k Ω	100 μA																				
30 k Ω	100 μA																				
100 k Ω	10 μA																				
300 k Ω	10 μA																				

Sweep characteristics	Available sweep parameters: Oscillator level, DC bias voltage, Frequency Sweep type: linear, log Sweep mode: single, double Sweep direction: up, down Number of measurement points: Maximum 1001 points
Measurement accuracy	The following parameters are used to express the impedance measurement accuracy at the measurement port of the MFCMU or the MFCMU cable (1.5 m or 3 m). Z_x: Impedance measurement value (Ω) D_x: Measurement value of D $E = E_P' + (Z_S'/ Z_x + Y_O' Z_x) \times 100$ (%) $E_P' = E_{PL} + E_{POSC} + E_P$ (%) $Y_O' = Y_{OL} + Y_{OSC} + Y_O$ (S) $Z_S' = Z_{SL} + Z_{OSC} + Z_S$ (Ω) Z accuracy $\pm E$ (%) θ accuracy $\pm E/100$ (rad) C accuracy at $D_x \leq 0.1$ $\pm E$ (%) at $D_x > 0.1$ $\pm E \times \sqrt{(1+D_x^2)}$ (%) D accuracy at $D_x \leq 0.1$ $\pm E/100$ at $D_x > 0.1$ $\pm E \times (1 + D_x)/100$ G accuracy at $D_x \leq 0.1$ $\pm E/D_x$ (%) at $D_x > 0.1$ $\pm E \times \sqrt{(1+D_x^2)}/D_x$ (%) Note: measurement accuracy is specified under the following conditions: Temperature: 23 ± 5 °C Integration time: 1 PLC

Parameters E_{POSC} , Z_{OSC}

Oscillator level	E_{POSC} (%)	Z_{OSC} (m Ω)
125 mV < $V_{\text{OSC}} \leq 250$ mV	$0.03 \times (250 / V_{\text{OSC}} - 1)$	$5 \times (250 / V_{\text{OSC}} - 1)$
64 mV < $V_{\text{OSC}} \leq 125$ mV	$0.03 \times (125 / V_{\text{OSC}} - 1)$	$5 \times (125 / V_{\text{OSC}} - 1)$
32 mV < $V_{\text{OSC}} \leq 64$ mV	$0.03 \times (64 / V_{\text{OSC}} - 1)$	$5 \times (64 / V_{\text{OSC}} - 1)$
$V_{\text{OSC}} \leq 32$ mV	$0.03 \times (32 / V_{\text{OSC}} - 1)$	$5 \times (64 / V_{\text{OSC}} - 1)$

V_{OSC} is oscillator level in mV.

Parameters E_{PL} , Y_{OL} , Z_{SL}

Cable length	E_{PL} (%)	Y_{OL} (nS)	Z_{SL} (m Ω)
1.5 m	$0.02 + 3 \times f / 100$	$750 \times f / 100$	5.0
3 m	$0.02 + 5 \times f / 100$	$1500 \times f / 100$	5.0

f is the frequency in MHz. If the measurement cable is extended, open compensation, short compensation, and load compensation must be performed.

Parameters Y_{OSC} , Y_{O} , E_{P} , Z_{S}

Frequency	Y_{OSC} (nS)	Y_{O} (nS)	E_{P} (%)	Z_{S} (m Ω)
1 kHz $\leq f \leq 200$ kHz	$1 \times (125 / V_{\text{OSC}} - 0.5)$	1.5	0.095	5.0
200 kHz < $f \leq 1$ MHz	$2 \times (125 / V_{\text{OSC}} - 0.5)$	3.0	0.095	5.0
1 MHz < $f \leq 2$ MHz	$2 \times (125 / V_{\text{OSC}} - 0.5)$	3.0	0.28	5.0
2 MHz < f	$20 \times (125 / V_{\text{OSC}} - 0.5)$	30.0	0.28	5.0

f is the frequency in Hz.

V_{OSC} is oscillator level in mV.

Example of calculated C/G measurement accuracy

Frequency	Measured capacitance	C accuracy ¹	Measured conductance	G accuracy ¹
5 MHz	1 pF	$\pm 0.61\%$	$\leq 3 \mu\text{S}$	$\pm 192 \text{ nS}$
	10 pF	$\pm 0.32\%$	$\leq 31 \mu\text{S}$	$\pm 990 \text{ nS}$
	100 pF	$\pm 0.29\%$	$\leq 314 \mu\text{S}$	$\pm 9 \mu\text{S}$
	1 nF	$\pm 0.32\%$	$\leq 3 \text{ mS}$	$\pm 99 \mu\text{S}$
1 MHz	1 pF	$\pm 0.26\%$	$\leq 628 \text{ nS}$	$\pm 16 \text{ nS}$
	10 pF	$\pm 0.11\%$	$\leq 6 \mu\text{S}$	$\pm 71 \text{ nS}$
	100 pF	$\pm 0.10\%$	$\leq 63 \mu\text{S}$	$\pm 624 \text{ nS}$
	1 nF	$\pm 0.10\%$	$\leq 628 \mu\text{S}$	$\pm 7 \mu\text{S}$
100 kHz	10 pF	$\pm 0.18\%$	$\leq 628 \text{ nS}$	$\pm 11 \text{ nS}$
	100 pF	$\pm 0.11\%$	$\leq 6 \mu\text{S}$	$\pm 66 \text{ nS}$
	1 nF	$\pm 0.10\%$	$\leq 63 \mu\text{S}$	$\pm 619 \text{ nS}$
	10 nF	$\pm 0.10\%$	$\leq 628 \mu\text{S}$	$\pm 7 \mu\text{S}$
10 kHz	100 pF	$\pm 0.18\%$	$\leq 628 \text{ nS}$	$\pm 11 \text{ nS}$
	1 nF	$\pm 0.11\%$	$\leq 6 \mu\text{S}$	$\pm 66 \text{ nS}$
	10 nF	$\pm 0.10\%$	$\leq 63 \mu\text{S}$	$\pm 619 \text{ nS}$
	100 nF	$\pm 0.10\%$	$\leq 628 \mu\text{S}$	$\pm 7 \mu\text{S}$
1 kHz	100 pF	$\pm 0.92\%$	$\leq 63 \text{ nS}$	$\pm 6 \text{ nS}$
	1 nF	$\pm 0.18\%$	$\leq 628 \text{ nS}$	$\pm 11 \text{ nS}$
	10 nF	$\pm 0.11\%$	$\leq 6 \mu\text{S}$	$\pm 66 \text{ nS}$
	100 nF	$\pm 0.10\%$	$\leq 63 \mu\text{S}$	$\pm 619 \text{ nS}$

1. The capacitance and conductance measurement accuracy is specified under the following conditions:

$Dx \leq 0.1$

Integration time: 1 PLC

Test signal level: 30 mV_{rms}

At the four-terminal pair port of MFCMU

Device Capacitance Selector (N1272A) Specification

The N1272A simplifies 2 and 3-terminal device capacitance measurements by automatically creating the correct configuration of test resources (including adding any needed DC blocking capacitors and AC blocking resistors) for a specified capacitance measurement. The N1273A Capacitance Test Fixture is also necessary to measure packaged device capacitance. However, the N1272A can be used directly with a probe station to measure on-wafer device capacitances.

DC bias characteristics

100 k Ω at SMU bias output resistance

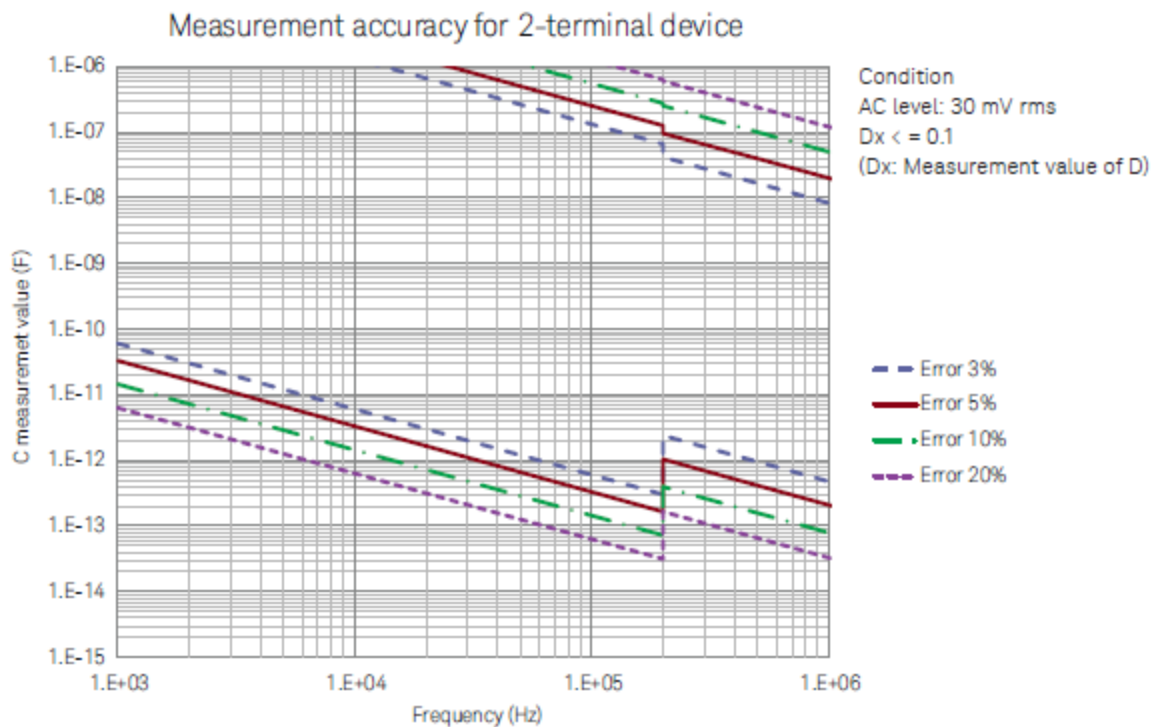
The voltage drop compensation function is available

Bypass capacitance in the capacitance selector

	Capacitance	Withstand voltage
Drain to the source terminal	1 μ F	$\pm$ 3000 V
Gate to the source terminal	1 μ F	$\pm$ 100 V

Measurement accuracy for a 2-terminal device (Supplemental characteristics)

The accuracy of the supplemental characteristics is defined at the output terminals of the TO socket adapter in the N1273A Capacitance Test Fixture when the N1272A is connected to B1505A with the 1.5 m CMU cable and the N1273A system cable.



Output terminals for 2-terminal device

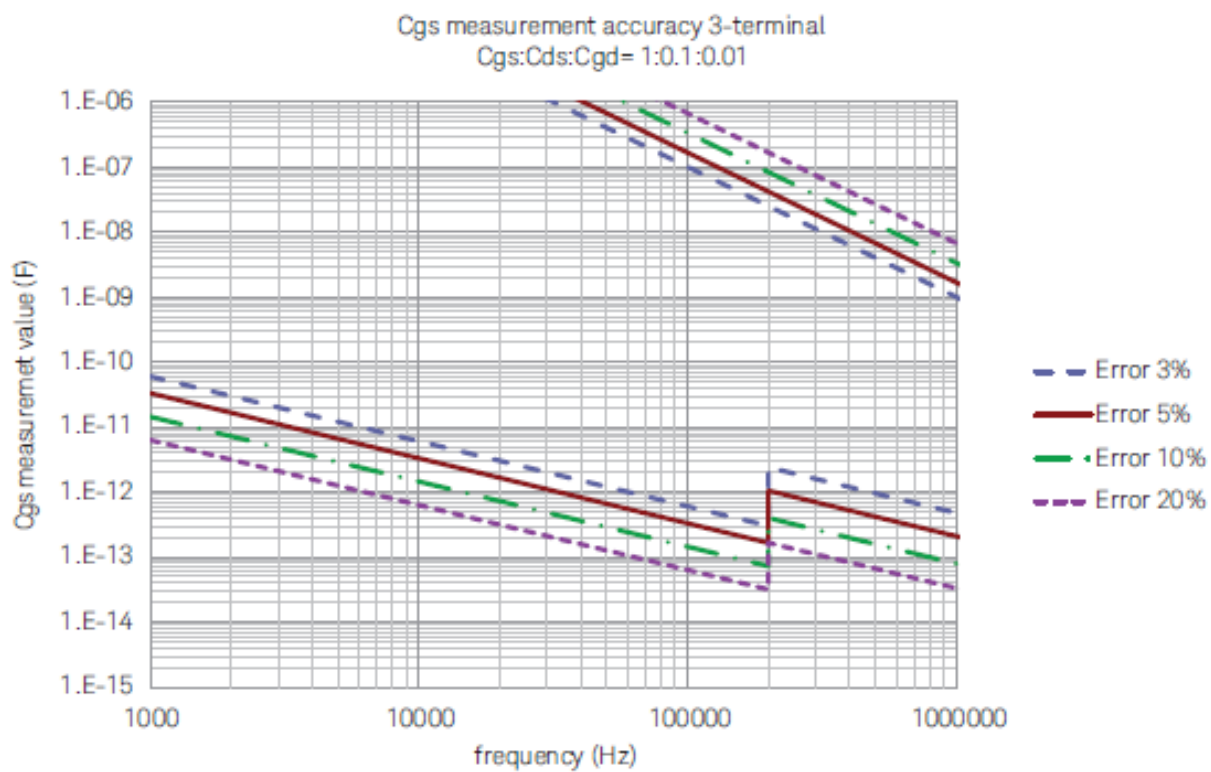
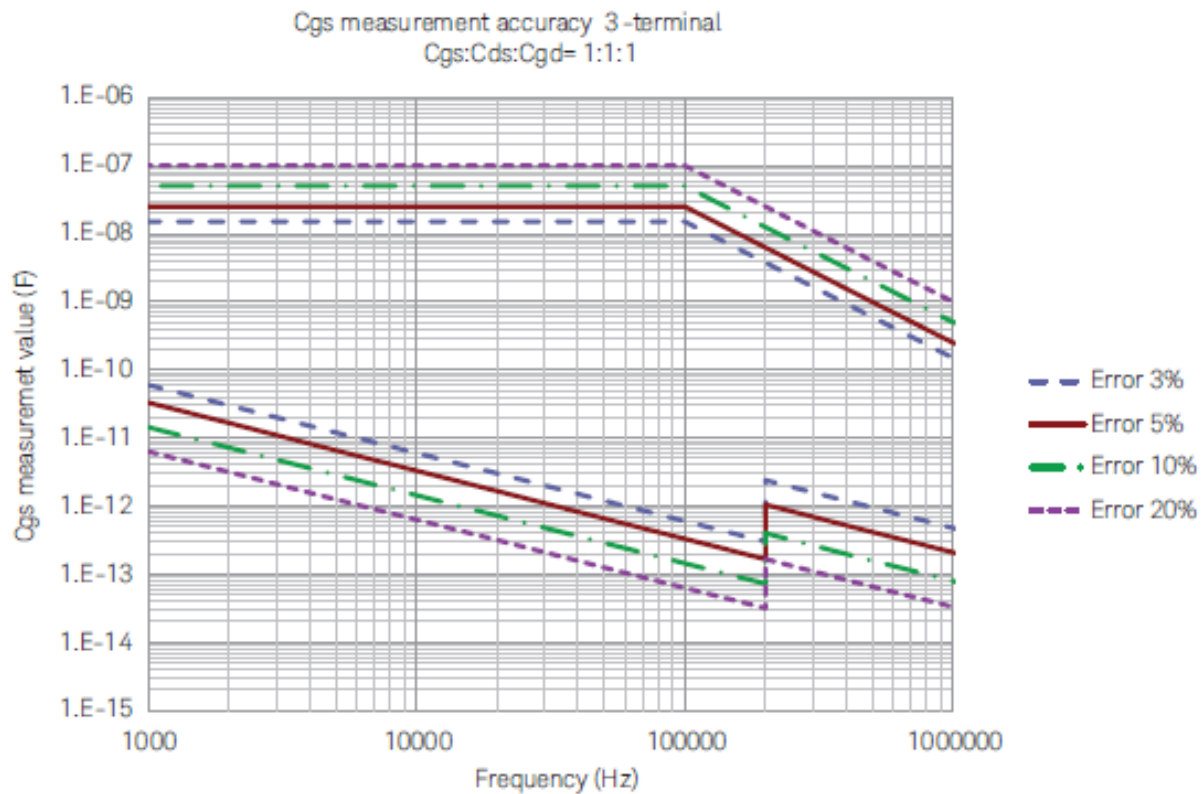
Collector/drain	High	High	
Emitter/source		Low	High
Base/gate	Low		Low

Measurement accuracy for a 3-terminal device (Supplemental characteristics)

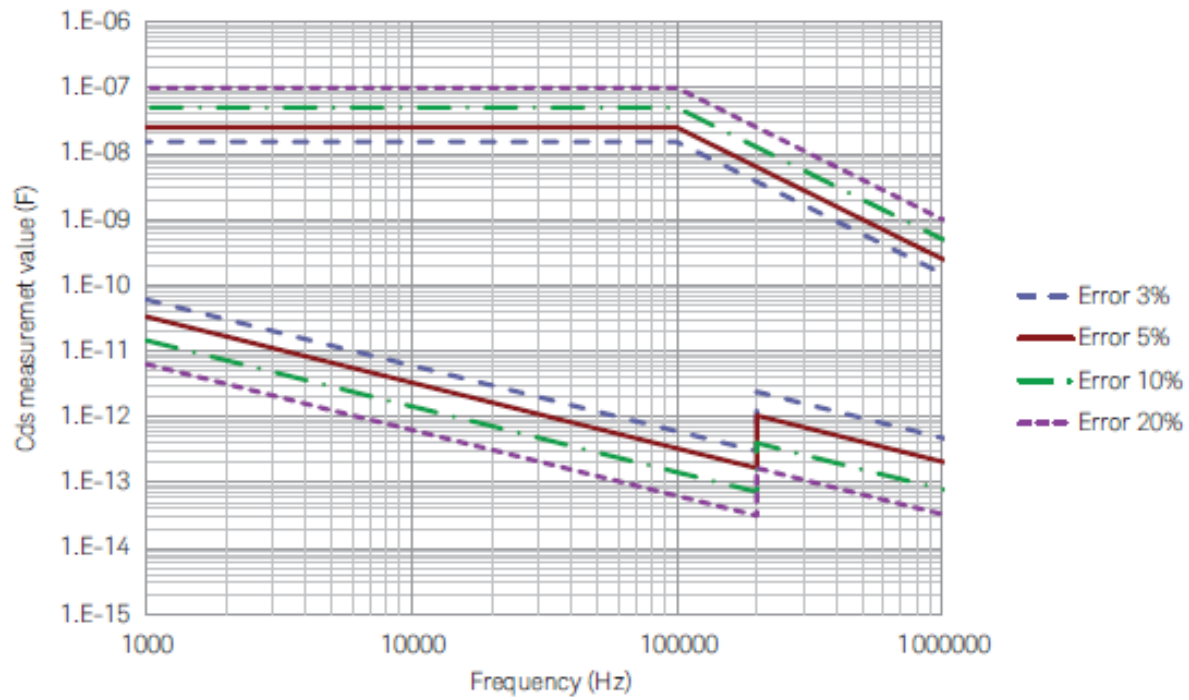
The accuracy of these supplemental characteristics is defined at the output terminals at the TO socket adapter in the N1273A Capacitance Test Fixture when N1272A is connected to B1505A with CMU 1.5 m cable and to the N1273A with system cable.

Condition

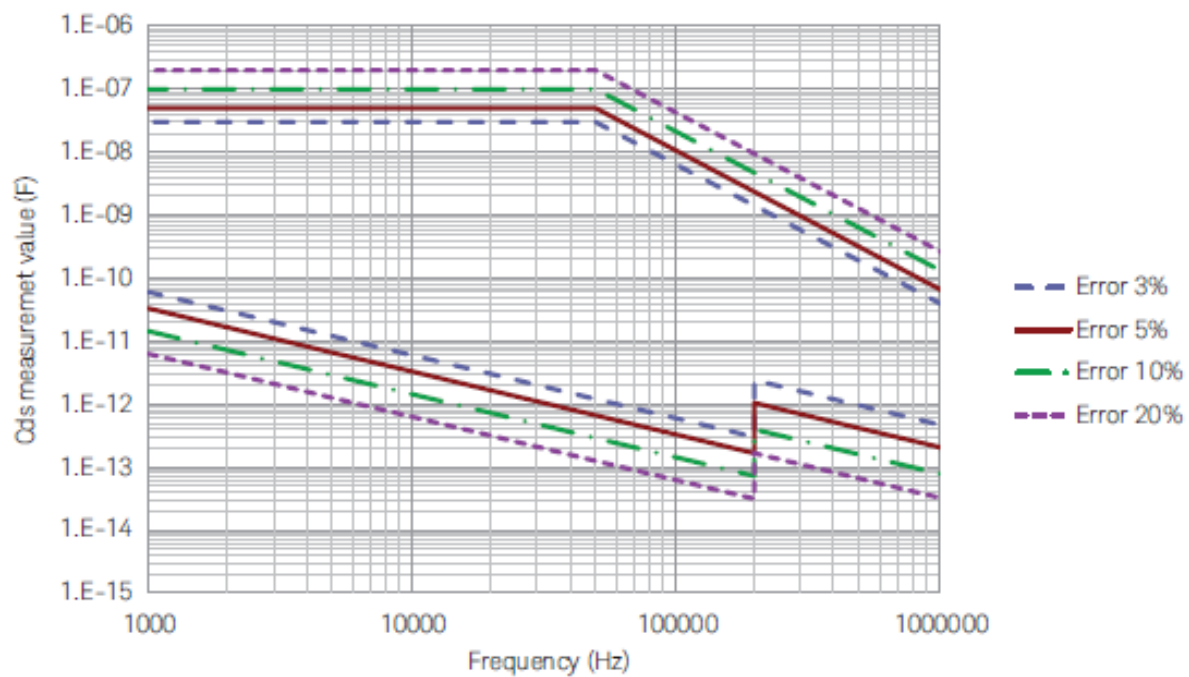
AC level: 30 mV rms, $Dx < 0.1$ (Dx: Measurement value of D)



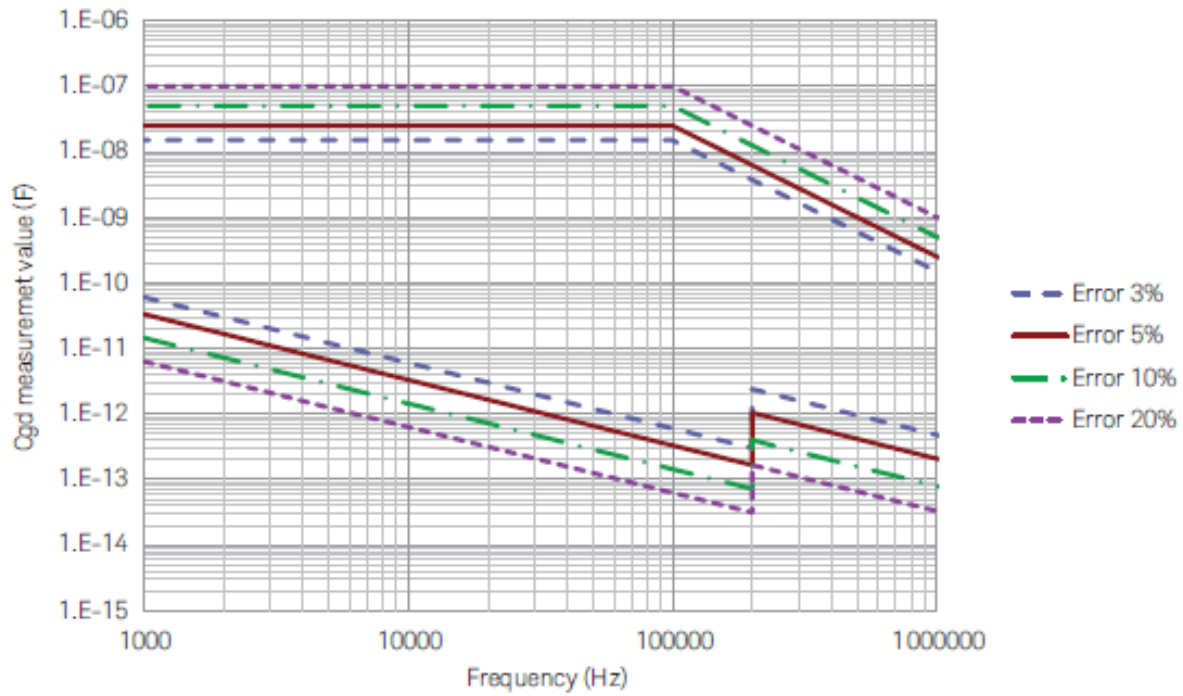
Cds measurement accuracy 3-terminal
Cgs:Cds:Cgd = 1:1:1



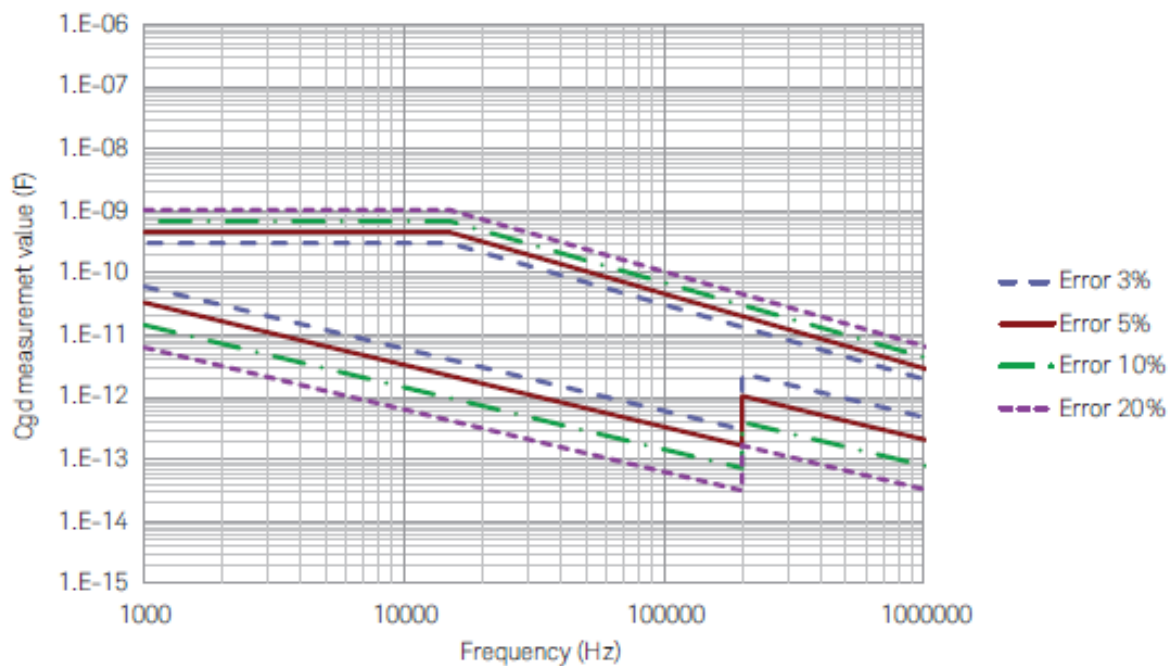
Cds measurement accuracy 3-terminal
Cgs:Cds:Cgd = 1:0.1:0.01



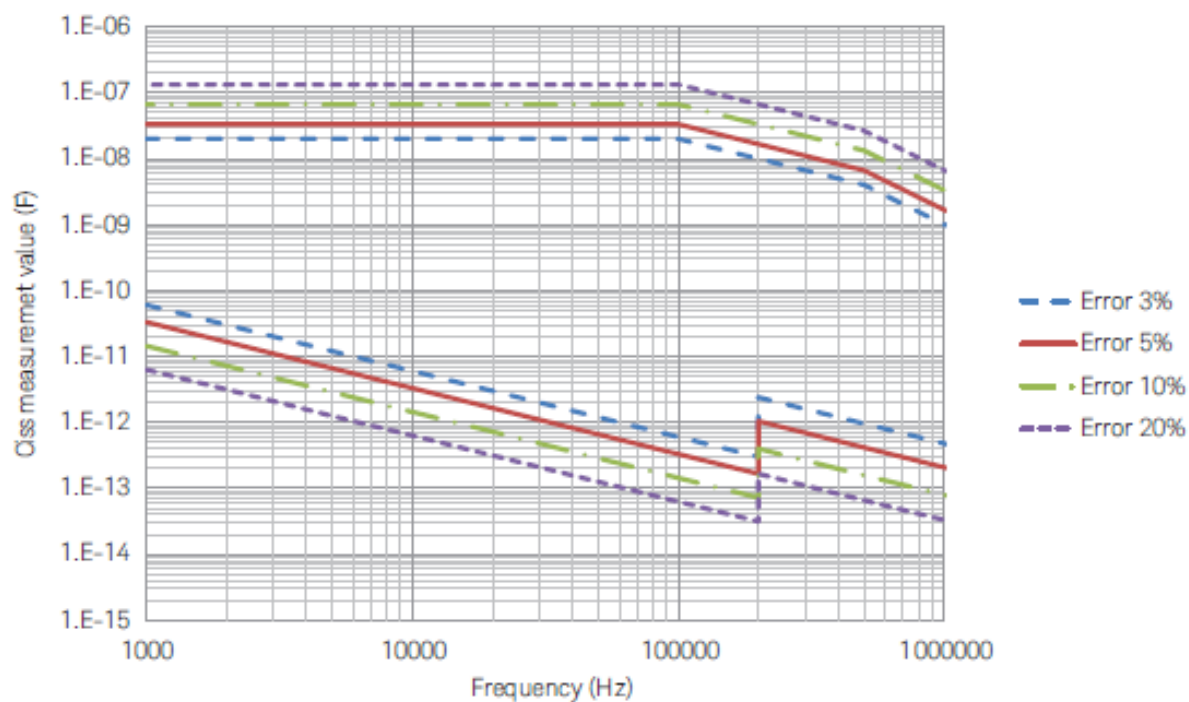
Cgd measurement accuracy 3-terminal
Cgs:Cds:Cgd = 1:1:1



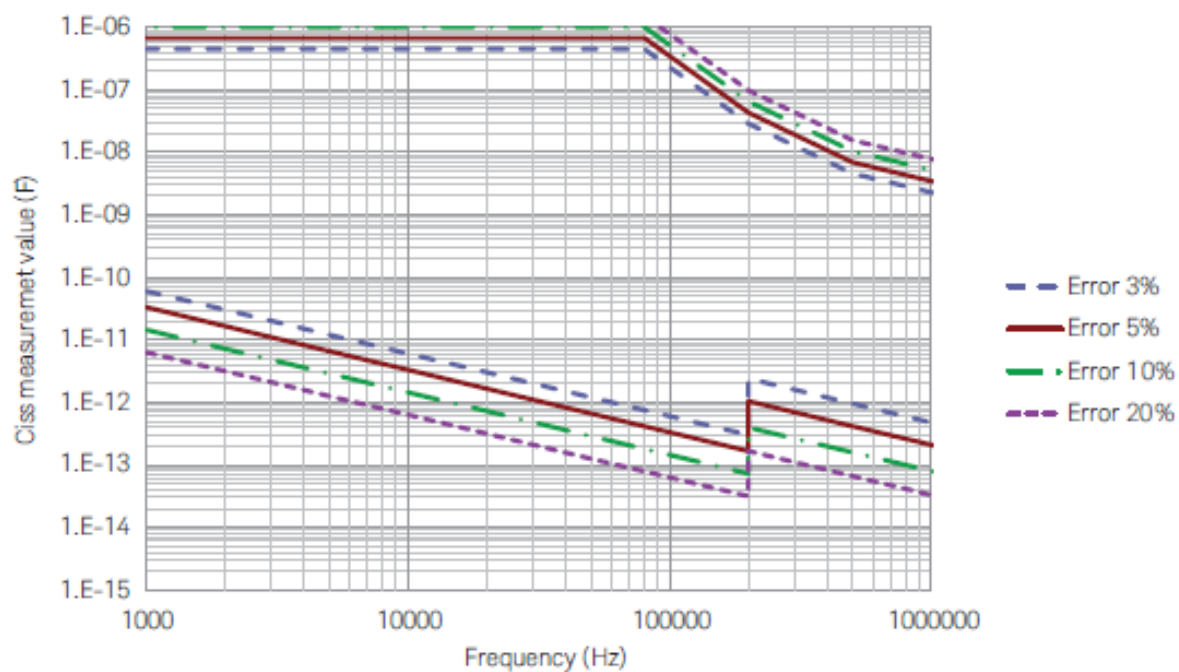
Cgd measurement accuracy 3-terminal
Cgs:Cds:Cgd = 1:0.1:0.01



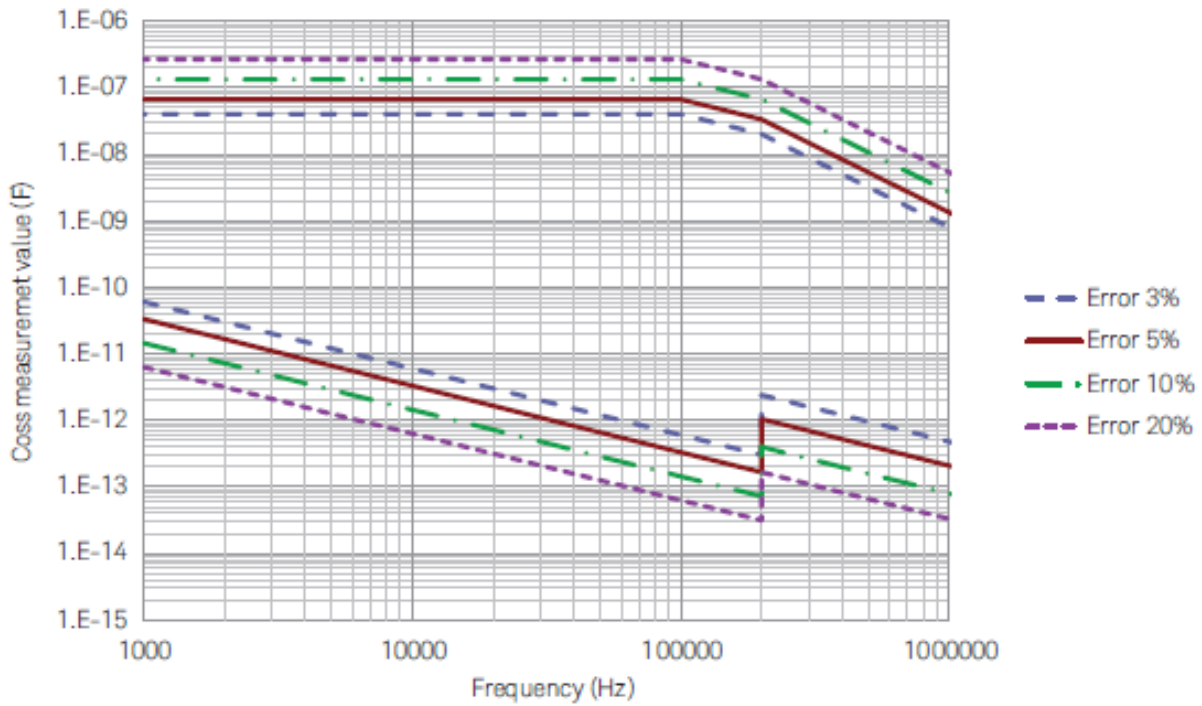
Ciss measurement accuracy 3-terminal
Cgs:Cds:Cgd = 1:1:1



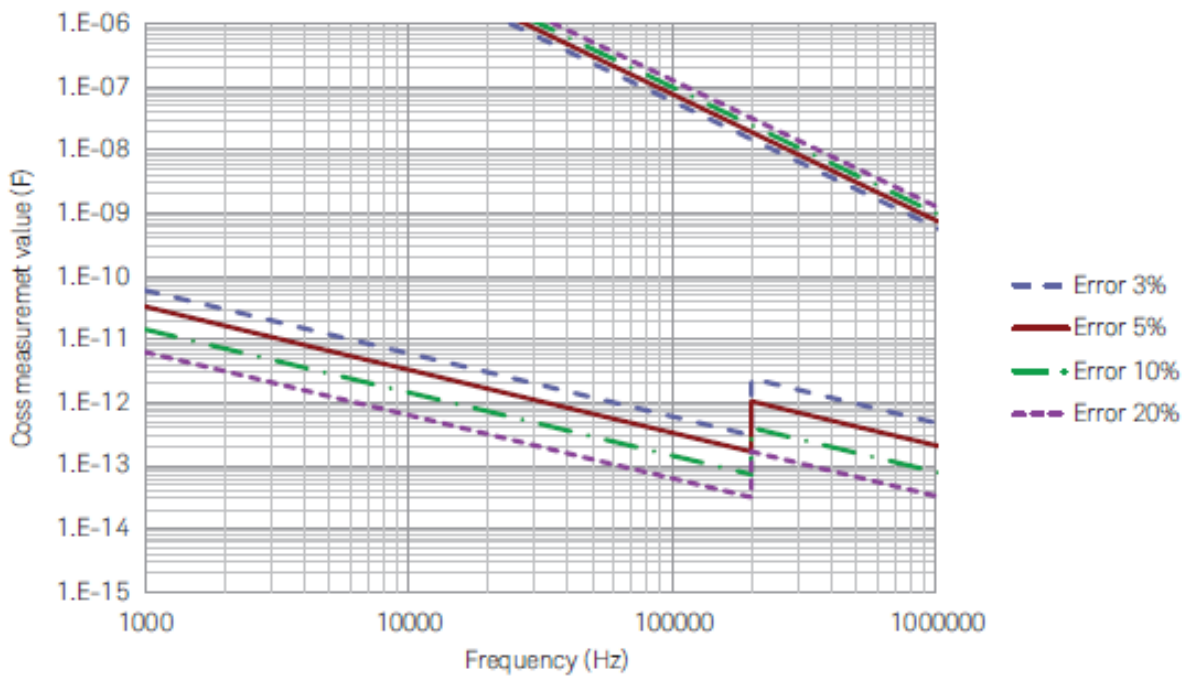
Ciss measurement accuracy 3-terminal
Cgs:Cds:Cgd = 1:0.1:0.01



Coss measurement accuracy 3-terminal
Cgs:Cds:Cgd = 1:1:1



Coss measurement accuracy 3-terminal
Cgs:Cds:Cgd = 1:0.1:0.01



Specifications

DC path leakage (Supplemental characteristics)	HVSMU port input / Drain output • Offset: 100 pA • Leakage: $V_o \times 1E-13$ (V_o: Output voltage) HVSMU port input / Direct output • Offset: 100 pA • Leakage: $V_o \times 1E-13$ (V_o: Output voltage) MPSMU port input / Gate output • Offset: 50 pA • Leakage: $V_o \times 5E-13$ (V_o: Output voltage)
Selector information	This information is provided for users not utilizing the N1273A capacitance test fixture but who wish to connect the selector outputs to other DUT interfaces, such as a wafer prober. Functionality Selector capability The selector allows the user to make connections to perform various capacitance and DC measurements such as leakage, breakdown, and threshold voltage measurement. Output terminals: • HV Triaxial: 1 ea. • SHV terminals: 4 ea. ◦ Gate/Base ◦ Drain/Collector ◦ Source/Emitter ◦ AC/DC guard • Interlock terminal: 1 ea • Digital I/O port: 1 ea. (D-sub 25 pin) Indicators Input terminals • HV Triaxial: 1 ea. (HVSMU) • Triaxial: 3 ea. (MPSMU Force/ Sense, GNDU) • BNC: 4 ea. (MCSMU Hcur, Lcur, Hpot, Lpot) • Interlock terminal: 1 ea, Direct IO

Output terminals for 3-terminal device

Parameter name		Coss	Cds	Crss	Cgs	Ciss /Rg
Collector/drain	Force	Open	Open	Open	Open	Open
	Sense	High	High	High	AC Guard	Low
Emitter/source	Force	Open	Open	Open	Open	Open
	Sense	Low	Low	Low	AC Guard	Low
Base/gate	High	Low	AC Guard	Low	High	High
	Low	Open	Open	Open	Open	Open

Definition of 3-terminal device capacitances

Symbol	Description
Cgs	Capacitance between Base/Gate terminal and Emitter/Source terminal
Cds	Capacitance between Collector/Drain terminal and Emitter/Source terminal
Cgd	Capacitance between Base/Gate terminal and Collector/Drain terminal
Crss	Capacitance between Base/Gate terminal and Collector/Drain terminal
Ciss	Capacitance between Base/Gate terminal and Emitter/Source terminal and capacitance between Base/Gate terminal and Collector/Drain terminal
Coss	Capacitance between Collector/Drain terminal and Emitter/Source terminal and capacitance between Base/Gate terminal and Collector/Drain terminal

UHC (Ultra High Current) Expander / Fixture (N1265A) Specifications

Specifications

Functions

Fixture capability

Current expander capability

Expands the B1505A's current capability up to 1500 A. The current expansion is made using the Ultra High Current Unit (UHCU), which is comprised of an external module and either two MCSMUs, two HCSMUs, or one MCSMU and one HCSMU.

Selector capability

This allows the user to switch the output between the UHCU and other modules connected to the selector input ports. The modules supported on the high-voltage input port are the HVSMU and HVMCU; the modules supported on the SMU input port are the HPSMU and MPSMU.

Channel	Number	Input	Output
SMU	6 (When using non-Kelvin connections) 3 (When using Kelvin connections)	Triaxial ¹	Banana
UHV	1	UHV coaxial (High), SHV (Low)	UHV coaxial (High), SHV (Low)
Bias Tee	1	SHV x 2(High, Low)	SHV x 2 (High, Low)
Gate control	1	Triaxial x 2 (Force, Sense)	Banana x 2 (High, Low)
Selector	1 ²	HV Triaxial x 1 Triaxial x 2 (Force, Sense)	Banana x 6 (High Force/Sense, Low Force/Sense, Guard, Chassis)

1. Either the HCSMU or the Dual HCSMU can be connected to the SMU 3 port.

2. The UHCU or any module connected to one of the other two selector input terminals can be connected to the output terminal.

Maximum output for selector channel

- HVSMU Output: ± 3000 V/4 mA, ± 1500 V/8 mA
- HVMCU Output: ± 2200 V/1.1 A, ± 1500 V/2.5 A
- HPSMU Output: ± 200 V/1 A
- MPSMU Output: ± 100 V/100 mA
- UHCU Output: ± 60 V/1500 A or 500 A
- Refer to each module specification.

Gate control channel

- Non-Kelvin connection
- Maximum Voltage: ± 40 V
- Maximum Current: ± 1 A Pulse, 100 mA DC.
- Output Resistance: 0 Ω /10 Ω /100 Ω /1000 Ω (nominal value)

UHCU

Output peak power

Current range	Peak power
± 500 A	7.5 kW
± 1500 A	22.5 kW

Voltage range, resolution, and accuracy

Voltage range	Setting resolution	Measure resolution	Setting accuracy ^{1,2,3} $\pm$ (% + mV)	Measure accuracy ^{1,3} $\pm$ (% + mV)
± 60 V	200 μ V	100 μ V	$\pm(0.2 + 10)$	$\pm(0.2 + 10)$

1. $\pm$ (% of reading value + fixed offset in mV)

2. Setting accuracy is defined at open load.

3. Accuracy is defined as 1 ms pulse width at the 500 A range and 500 μ s pulse width at the 1500 A range.

Current range, resolution, and accuracy ¹

Current range	Setting resolution	Measure resolution	Setting accuracy ^{2,3} $\pm$ (% + A + A)	Measure accuracy ^{2,3} $\pm$ (% + A + A)
± 500 A	1 mA	500 μ A	$\pm(0.6 + 0.3 + 0.01 \cdot V_o)$	$\pm(0.6 + 0.3 + 0.01 \cdot V_o)$
± 1500 A	4 mA	2 mA	$\pm(0.8 + 0.9 + 0.02 \cdot V_o)$	$\pm(0.8 + 0.9 + 0.02 \cdot V_o)$

1. Maximum voltage compliance in current pulse mode is 63 V. Over 400 A at 500 A range and over 1200 A at 1500 A range are supplemental characteristics.

2. Accuracy is defined with a 1 ms pulse width at the 500 A range and with a 500 μ s pulse width at the 1500 A range.

3. $\pm$ (% of reading value + fixed offset in A + proportional offset in A), V_o is the Output Voltage.

UHCU Pulse width and resolution

Current range	Voltage pulse width	Current pulse width	Resolution	Pulse period ¹
500 A	10 μ s – 1 ms	10 μ s – 1 ms	2 μ s	Duty $\leq 0.4\%$
1500 A	10 μ s – 500 μ s	10 μ s – 500 μ s	2 μ s	Duty $\leq 0.1\%$

1. At the continuous maximum current output, the output current may be reduced due to insufficient charging time.

Other functionality

Filter

- A filter can be used for UHC output in the current mode at the 500 A range.

Thermocouple input: 2 ea

- Two K-type thermocouple inputs
- Temperature range: -50 °C to 300 °C.

Other terminals/indicators

- Digital I/O input: 1 ea.
- Digital I/O output: 1 ea.
- Power indicator: 1 ea.
- High voltage indicator: 1 ea.
- Selector indicator: 1 ea.
- Interlock terminal: 1 ea.
- Earth terminal: 1 ea.
- Wrist strap terminal: 1 ea.

Supplemental characteristics

UHCU Output resistance

Output range	Nominal value
500 A	120 mΩ
1500 A	40 mΩ

Leakage

Selector channel

- HVSMU is applied at the High Sense terminal: less than 1 nA
- HPSMU/MPSMU is applied at the High Force terminal: less than 10 nA

UHVU channel

- Less than 1 nA

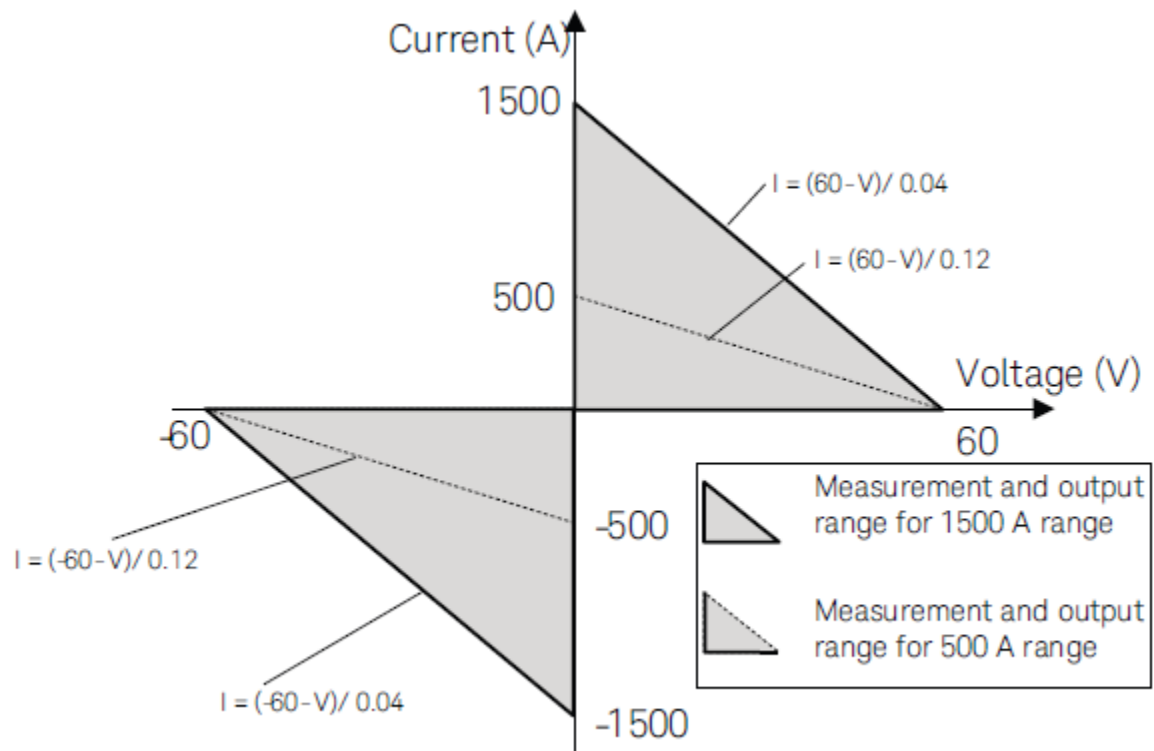
SMU channel

- Less than 1 nA

Thermocouple reading accuracy

Temperature range	Accuracy
$0^{\circ}\text{C} \leq T < 100^{\circ}\text{C}$	$\pm 2^{\circ}\text{C}$
$T \geq 100^{\circ}\text{C}$	$\pm 5^{\circ}\text{C}$
$T < 0^{\circ}\text{C}$	$\pm 5^{\circ}\text{C}$

UHC measurement and output range



The UHCU output is only available in pulsed mode.

In the equations in the above diagram, 'I' stands for current, and 'V' is for Voltage.

The maximum current is defined when the output terminals are shorted.

Also, the maximum current is limited by the residual resistance of the test leads, by contact resistance between the internal jumper cable and the DUT, and by the DUT impedance.

HVSMU Current Expander (N1266A)

Specifications

Specifications

Functions:

Current expander capability

Expands HVSMU current up to 2.5 A. The current expansion is made using the High Voltage Medium Current Unit (HVMCU), which is comprised of a module in the N1266A, HVSMU, and two MCSMUs.

Selector capability

This allows the connections between the output terminal to be switched between the HVMCU and the HVSMU. The HVSMU output can be routed either directly or through a 100 k Ω resistor.

Output Terminals:

- High (HV Triaxial)
- Low (BNC)

Maximum output:

- HVSMU: ± 3000 V/4 mA, ± 1500 V/8 mA
- HVMCU: Refer to HVMCU specification

HVMCU

Output peak power

Voltage range	Peak power
± 2200 V	600 W
± 1500 V	900 W

Voltage range, resolution, and accuracy

Voltage range	Setting resolution	Measure resolution	Setting accuracy ^{1,2,3} $\pm$ (% + V)	Measure accuracy ^{1,2} $\pm$ (% + V)
± 2200 V	3 mV	3 mV	$\pm(5 + 20)$	$\pm(0.8 + 1.8)$
± 1500 V	1.5 mV	3 mV	$\pm(5 + 20)$	$\pm(0.8 + 1.8)$

1. $\pm$ (% of reading value + fixed offset in V)

2. Accuracy is defined with 100 μ s pulse at 1.1 A range and 2.5 A range, 1 ms pulse at 100 mA range.

3. Setting accuracy is defined at open load.

Current range, resolution, and accuracy^{1, 2}

Current range	Measure resolution	Measure accuracy ¹ $\pm$ (% + A + A)
± 2.5 A	4 μ A	$\pm(0.9 + 4E-3 + V_o \times 3E-7)$
± 1.1 A	4 μ A	$\pm(0.9 + 4E-3 + V_o \times 3E-7)$
± 110 mA	200 nA	$\pm(0.9 + 2E-4 + V_o \times 3E-7)$

1. Supplemental characteristics over 1.1 A.

2. Applicable condition: 20 averaging samples

HVMCU Pulse width and resolution

Output range	Pulse width	Resolution
1500 V / 2.5 A	10 μ s – 100 μ s	2 μ s
2200 V / 1.1 A	10 μ s – 100 μ s	2 μ s
2200 V / 110 mA	10 μ s – 1 ms	2 μ s

Other terminals / Indicators

- Digital I/O Input: 1 ea.
- Digital I/O output: 1 ea.
- Power indicator: 1 ea
- Selector indicator: 1 ea

Supplemental characteristics

HVMCU Charged Capacitance: 0.22 μ F

Output resistance

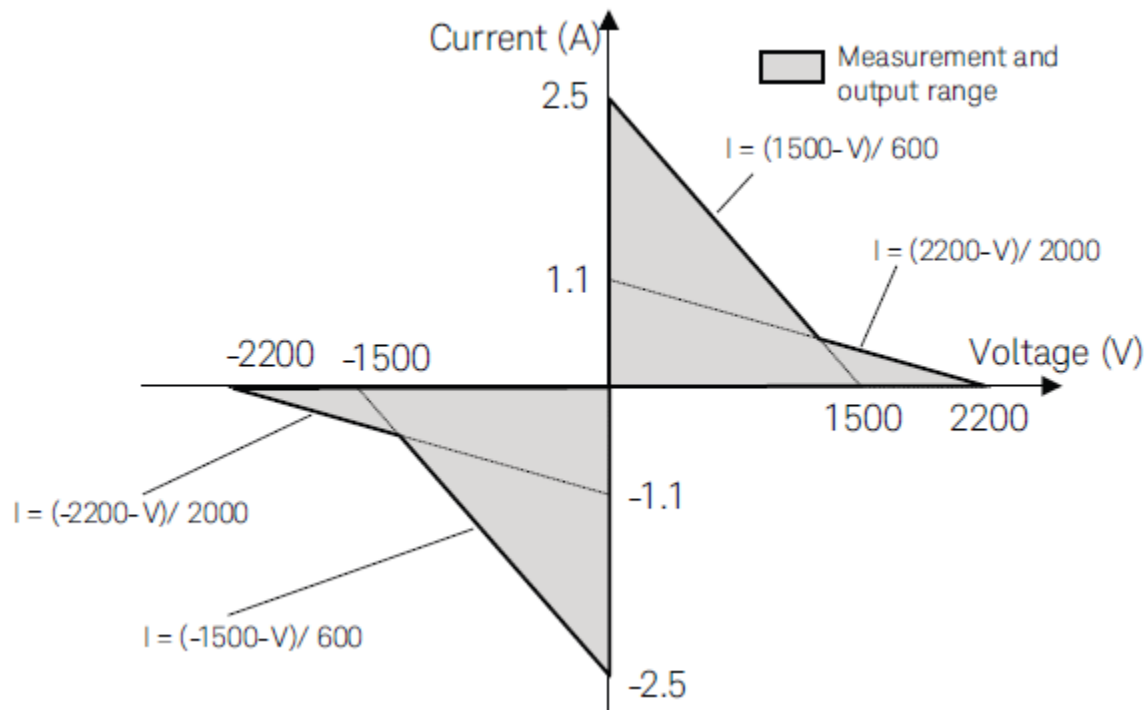
Output range	Nominal value
1500 V / 2.5 A	600 Ω
2200 V / 1.1 A	2000 Ω
2200 V / 110 mA	20000 Ω

Leakage

Selector output

HVSMU: less than 300 pA

HVMCU measurement and output range



The HVMC's output is only available in pulsed mode.

In the equations in the above diagram, 'I' stands for current, and 'V' is for Voltage.

The maximum current is defined when the output terminals are shorted.

Also, the maximum current is limited by the residual resistance of the test leads, by contact resistance between the internal jumper cable and the DUT, and by the DUT impedance.

UHV (Ultra High Voltage) Expander (N1268A) Specifications

Specifications

Voltage range, resolution, and accuracy ¹

Voltage range	Force resolution	Measure resolution	Setting accuracy ^{2,3} $\pm$ (% + V)	Measure accuracy ² $\pm$ (% + V)
± 10 kV	10 mV	10 mV	$\pm(1.2 + 42)$	$\pm(1.2 + 42)$

1. N1268A is controlled and makes measurements with two MCSMUs or a combination of an HCSMU and an MCSMU.

2. $\pm$ (% of reading value + fixed offset in V)

3. Setting accuracy is defined at open load.

Current range, resolution, and accuracy ¹

Current range	Measure resolution	Measure accuracy ² $\pm$ (% + A + A)
± 10 μ A	10 pA	$\pm(0.06 + 2E-9 + 1E-9)$
± 100 μ A	100 pA	$\pm(0.06 + 2E-8 + 1E-9)$
± 1 mA	1 nA	$\pm(0.06 + 2E-7 + 1E-9)$
± 10 mA	10 nA	$\pm(0.06 + 2E-6 + 1E-9)$
± 100 mA ³	100 nA	$\pm(0.06 + 20E-6 + 1E-9)$

1. N1268A is controlled and makes measurements with two MCSMUs or a combination of an HCSMU and an MCSMU.

2. $\pm$ (% of reading value + fixed offset in A + fixed offset in A)

3. Pulsed mode only (Maximum pulse width is 1 ms). The maximum current is 20 mA.

UHV Pulse width and resolution

Output range	Pulse width	Resolution
100 mA	100 μ s to 1 ms	2 μ s
≤ 10 mA	100 μ s to 2 s	2 μ s

Pulse period

- Min: 10 ms
- Max: 5 s

Output terminals

- High: UHV coaxial
- Low: SHV

Other terminals / indicators

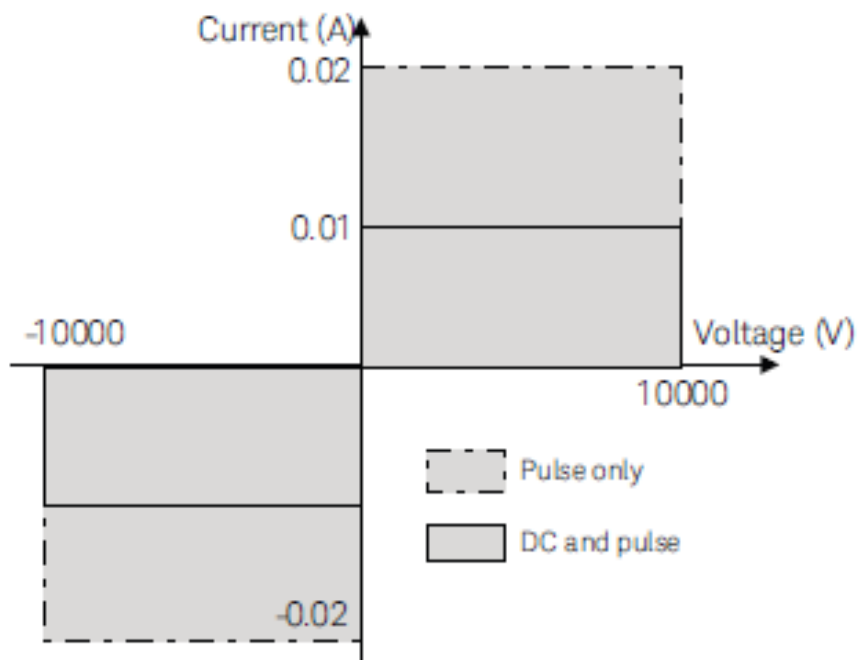
- Digital I/O input: 1 ea.
- Power indicator: 1 ea
- High voltage indicator: 1 ea
- Interlock terminal input: 1 ea
- Interlock terminal output: 1 ea
- Earth terminal: 1 ea

Supplemental characteristics

UHVU output resistance

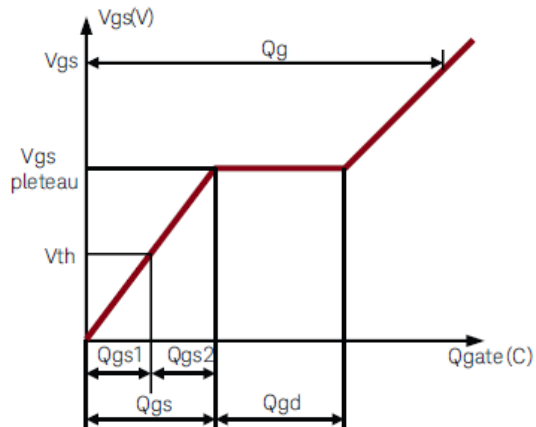
Output range	Nominal value
High	10000 Ω
Low	1000 Ω
Other AC characteristics	
Slew rate	100 V/ μ s (with 1 m cable)
Overshoot	$\pm 1\%$ of setting voltage
Ripple	3 Vp-p
Maximum load capacitance	5 nF
Maximum load inductance	5 μ H

UHV measurement and output range



Gate charge measurement specifications

The B1505A can perform gate charge characterization for Nch MOSFETs and IGBTs. Both packaged devices and on-wafer devices are supported. The following table shows the available solutions and their required accessories (which depend on device type and current level). Temperature-dependent measurements using a Thermostream or the Thermal plate are not supported.



Q_g : Gate charge
 Q_{gs} : Gate-source charge
 Q_{gs1} : Gate charge at threshold
 Q_{gs2} : Gate charge from threshold to onset of plateau
 Q_{gd} : Gate-drain charge

Hardware configuration and measurement/setting parameters

Hardware configuration and measurement/setting parameters

		Package solution				On-wafer solution		
Hardware configuration	High voltage module	B1513B/C HVSMU						
	Max voltage range	3000 V						
	High current module	B1512A HCSMU	N1265A-500	N1265A-1500A	B1512A HCSMU	N1265A-500A	N1265A-1500A	
	Max current range	20 A	500 A	1500 A	20 A	500 A	1500 A	
	Gate control module	B1514A MCSMU						
	Ireg control module	B1514A MCSMU						
	Fixture/selector	N1259A	N1265A		N1258A	N1265A		
	Adapter/selector	N1259AU-014	N1265AU-014		N1274A	N1275A		
Measurement parameter	Qg	1 nC to 100 μC						
	Min resolution	10 pC						
	Vds (vce) @high voltage	0 V to +3000 V						
	Voltage/sampling resolution	3 mV / 6 us						
	Vds(vce) @ high current	Not Support	-60 V to 60 V		Not Support	-60 V to 60 V		
	Voltage /sampling resolution	Not Support	100 μV / 2 μs		Not Support	100 μV / 2 μs		
	Id (ic) maximum rated current	20 A ¹	350 A ¹	500 A ^{1,2}	20 A ¹	350 A ¹	500 A ^{1,2}	
	Current/sampling resolution	2 mA / 2 μs						
	Vgs (vge)	-30 V to +30 V						
	Voltage/sampling resolution	40 μV / 2 μs						
	Ig	10 nA to 1 A						
	Current/sampling resolution	10 pA / 2 μs						
Setting parameters	Vds (vce) @high voltage	0 V to +3000 V						
	Resolution	3 mV						
	Vds(vce) @ high current	-20 to 20 V ¹	-60 to 60 V		-40 to 40 V ¹	-60 to 60 V		
	Resolution	20 μV	100 μV		40 μV	100 μV		
	Id max	20 A ¹	450 A ¹	1100 A ^{1,2}	20 A ¹	350 A ¹	500 A ¹	
	Gate drive vgs(vge)	-30 to +30 V						
	Resolution	40 μV						
	Gate control current ig	1 μA to 1 A						
	Resolution	0.1 μA						
	Current regulator control voltage	-30 to +30 V						
	Resolution	40 μV						
	On time	50 - 950 μs	50 - 950 μs		50 - 950 μs	50 - 950 μs		
	Resolution	2 μs						

1. The maximum current will be reduced by the series resistance of the current source, residual resistance in the measurement path, and the DUT impedance.

2. The gate charge measurement adapter also has a maximum current limit of 500 A.

Target devices:

- Nch MOSFETs and IGBTs in TO package, in modules and on-wafer
- Note that Pch MOSFETs are not supported.

N1267A High Voltage Source Monitor Unit / High Current Source Monitor Unit Fast Switch

Features

The N1267A supports fast switching between the HVSMU and HCSMU to enable the measurement of the Gallium Nitride current collapse effect.

The N1267A switch requires one MCSMU in the B1505A mainframe for control. The gate of the DUT (Device Under Test) can be driven by either an MCSMU or an HCSMU.

- Note #1: The N1267A can only be used with the B1513B or B1513C HVSMU; it cannot be used with the B1513A HVSMU.
- Note #2: The N1267A does not support the two HCSMU 40 A configurations.
- Note #3: The N1267A does not support the N1265A test fixture/current expander.

Specifications

Input terminals:

- HVSMU port, 1 ea (HV triaxial)
- HCSMU port, 1 ea (Force: BNC, Sense: Triaxial)
- MCSMU port, 1 ea (Force/Sense: Triaxial)
- GND port, 1 ea (Triaxial)
- Output terminals: High (HV triaxial), Low (BNC)
- Maximum current: 20 A
- Maximum voltage: 3000 V

Measurement mode

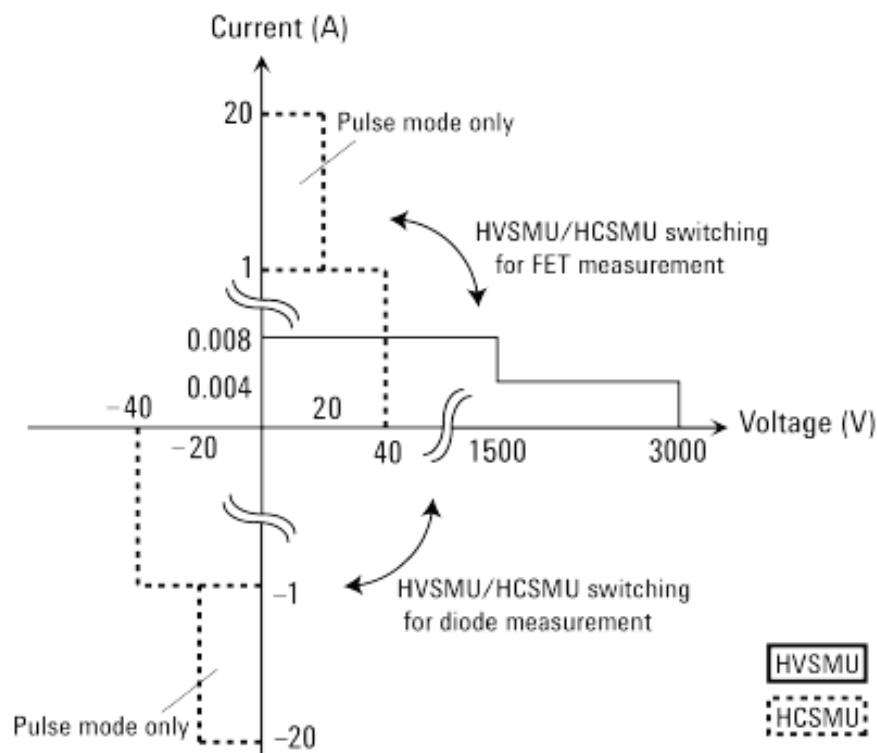
GaN Current collapse (Dynamic I-V) measure mode

1. I-V time domain measurement
2. I-V trace measurement

Static characteristics mode

3. I_d - V_{ds} , V_f - I_f measurement
4. $I_d(\text{off})$ - V_{ds} , V_r - I_r measurement

Source and measure range



GaN current collapse measure mode

To make the GaN current collapse measurement, the HVSMU first applies high voltage stress to the DUT when the DUT is in the OFF-state. Next, the HVSMU performs voltage measurement, and the HCSMU performs I-V measurement to monitor the ON-state characteristics of the DUT. When making the ON-state measurement, the HVSMU measures voltage, and the HVSMU and HCSMU are used to measure the total current.

HVSMU Source setting range for OFF-state

Voltage	Current
+1 V - +3000 V ¹	4 mA (V > 1500 V), 8 mA (V ≤ 1500 V)
1. The setting value must be the ON state voltage plus 1 V or more.	

HCSMU source setting range for ON-state

Voltage	Current	
0 V - ±40 V ²	Maximum	Minimum
	20 A pulse (V ≤ 20V) / 1 A DC	20 mA ³
2. Voltage actually applied to the device under test (DUT) is the setting value minus the voltage drop of the switch.		
3. The sum of HCSMU output current and HVSMU output current flow into DUT.		

- Minimum voltage measurement resolution for OFF-state: 200 μ V
- Minimum current measurement resolution for ON-state: 100 nA
- Minimum transition time (OFF to ON): 20 μ s
- Duration setting for OFF-state: 10 ms - 655.35 s
- Sampling rate: 2 μ s to 12 μ s for current, 6 μ s for voltage
- Minimum ON state duration: 50 μ s

Static characteristics mode

The following information applies to the measurement of the DUT ON-state static characteristics. The N1267A ensures that the DUT is in the ON-state during these measurements. The HVSMU applies 0 V with 1 μ A compliance and measures V_{ds} or V_f . At the same time, the HCSMU is also performing an I-V measurement. The I_d or I_f is determined by adding the total current measured by the HCSMU and the HVSMU.

HCSMU source setting for I_d - V_{ds} , V_f - I_f measurement

Voltage	Current	
	Maximum	Minimum
0 V - ± 40 V	20 A pulse ($V \leq 20$ V) / 1 A DC	20 mA ⁴

- Minimum voltage measurement resolution: 200 μ V
- Minimum current measurement resolution: 10 pA ⁴

⁴ Offset error for the I_d - V_{ds} , I_f - V_f measurement is typical 1 μ A

The following information applies to the measurement of the DUT OFF-state static characteristics. The N1267A ensures that the DUT is in the OFF-state during these measurements. The HCSMU applies 0 V. At the same time, the HVSMU performs I-V measurement and measures V_{ds} or V_r . The I_d (Off) or I_r is determined by adding the total current measured by the HCSMU and the HVSMU.

HVSMU source setting for I_d (off)- V_{ds} , V_r - I_r measurement

Voltage	Current	
	Maximum	Minimum
0 V - +3000 V	4 mA ($V > 1500$ V), 8 mA ($V \leq 1500$ V)	10 μ A ⁵

- Minimum voltage measurement resolution: 200 μ V
- Minimum current measurement resolution: 10 pA ⁵

⁵ Leak error for the I_{dss} , I_r - V_r measurement is typical 2 nA.

Accessories

N1258A module selector

N1258A module selector

Specification	
Input terminals	• HPSMU force port¹, 1 ea., (Triaxial) • HPSMU sense port¹, 1 ea., (Triaxial) • HCSMU force port, 1 ea. (BNC) • HCSMU sense port, 1 ea. (Triaxial) • HVSMU port², 1 ea. (HV triaxial) • GNDU port, 1 ea. (Triaxial) • Digital I/O port, 1 ea. (D-sub 25 pin) • AC power line connector, 1 ea. 1. Either HPSMU or MPSMU can be connected to the HPSMU port. 2. Either HVSMU or HVMCU can be connected to the HVSMU port.
Output terminal	• High force (HV triaxial) • High sense (HV triaxial) • Low force (BNC) • Low sense (BNC) • External relay control output • (D-sub 15 pin)
Protection	HPSMU, GNDU, HCSMU Low Force
Power indicator	LED turns yellow when AC power is applied and turns green the module selector is ready to use.
Status indicator	Green LED lights to indicate the present connection path of module selector; Open, HCSMU, HPSMU, or HVSMU.
Maximum voltage/current	For HPSMU port: • ± 200 V/1 A For HCSMU port: • ± 40 V/2 A, ± 20 V/30 A (Pulse width 1 ms, duty 1%) For HVSMU port: • ± 3000 V/4 mA, • ± 1500 V/2.5 A, ± 2200 V/1.1 A
Supplemental characteristics	
Leakage current	For HPSMU: • 40 pA at 200 V For HCSMU: • 100 pA at 10 V (High Force to Low Force, High Sense to Low Sense) For HVSMU: • 300 pA at 3000 V (humidity range: 20% to 50% RH)

N1259A test fixture

N1259A test fixture

Specification	
Input terminals	HPSMU port ¹, 2 ea. - Force, sense (Triaxial) HCSMU port, 2 ea. - Force (BNC), sense (Triaxial) HVSMU port ², 1 ea. (HV triaxial) - GNDU port, 1 ea. (Triaxial) - AUX port, 2 ea. (BNC) - Interlock port, 1 ea. 1. Either HPSMU or MPSMU can be connected to the HPSMU port. 2. Either HVSMU or HVMCU can be connected to the HVSMU port.
Protection	HPSMU, GNDU, HCSMU Low Force terminal
High voltage indicator	LED turns red when an SMU output voltage is over 42 V
Maximum voltage/current	For HPSMU port: - Force: ± 200 V/1 A - Sense: ± 200 V For HCSMU port: - High Force: ± 40 V/2 A, ± 20 V/40 A (Pulse width 1 ms, duty 1%) - Low Force: ± 40 V/2 A, ± 20 V/40 A (Pulse width 1 ms, duty 1%) - High Sense: ± 40 V - Low Sense: ± 40 V For HVSMU port: - Force: ± 3000 V/4 mA, ± 1500 V/2.5 A, ± 2200 V/1.1 A Note: The total power consumption of all modules cannot exceed 50 W when using the test fixture under the condition that the operating temperature is more than 35 °C.
Supplemental characteristics	
Leakage current	For HPSMU (Force, Sense) port: 40 pA at 200 V (Force, Sense) For HCSMU (High Force, High sense) port: 100 pA at 10 V For HVSMU (Force) port: 300 pA at 3000 V (humidity range: 20% to 50% RH)

N1259A-010 inline package socket module (3 pins)

N1259A-010 inline package socket module (3 pins)

Specification	
Number of terminals	Sockets, 6 ea. (Ø4 mm jack (banana))
DUT interface	Inline package socket (3-pin)
Maximum voltage for terminals	3000 Vdc

N1259A-011 universal socket module

N1259A-011 universal socket module

Specification	
Number of terminals	Sockets, 8 ea. (Ø4 mm jack (banana))
Maximum voltage for terminals	3000 Vdc

N1259A-013 Curve tracer test adapter socket module

N1259A-013 curve tracer test adapter socket module

Specification	
Number of terminals	Sockets, 6 ea. (Ø4 mm jack (banana))
Test adapter interface ¹	Sockets, 6 ea. (Ø4 mm jack (banana))
Maximum voltage at terminals	3000 V Vdc
Maximum current for terminals	For Collector/Drain Force and Emitter/Source Force 39 A (DC), 500 A (Pulse)
	For others 1 A (DC), 20 A (Pulse)

1. A test adapter for Tektronix curve tracers (370B/371B) can be connected to this interface.

N1259A-014 gate charge socket adapter

Purpose

To make gate charge measurements with the N1259A.

Required hardware

- N1259A test fixture, 1 ea.
- N1259A-300 Module selector, 1 ea.
- B1512A HCSMU, 1 ea.
- B1513B/C HVSMU, 1 ea.
- B1514A MCSMU, 2 ea.

N1259A-014 gate charge socket adapter

Specification	
Number of terminals	Sockets, 8 ea. (Ø4 mm jack (banana))
Maximum voltage at terminals	• For Gate DUT High: 30 V • For Gate DUT Low: 10 V • For selector force High: 3000 V • For selector force Low: 10 V • For selector sense High: 3000 V • For selector sense Low: 10 V • For SMU control High: 30 V • For SMU control Low: 10 V
Maximum current for terminals	• For Gate DUT High: 1 A • For Gate DUT Low: 1 A • For selector force: 500 A • For selector sense: 20 mA • For SMU control: 1 A

Furnished accessories

- Test lead (red), short, 2 ea.
- Test lead (black), short, 2 ea.
- Test lead (red), long, 4 ea.
- Test lead (black), long, 4 ea.

N1259A-020 high voltage bias-tee

N1259A-020 high voltage bias-tee

Specification	
Input terminals	DC bias input, 1 ea. (Ø4 mm jack (banana))
	MFCMU port, 1 ea. Hcur, Hpot, Lcur, Lpot, (BNC)
	Guard input, 1ea (Ø4 mm banana jack)
Output terminal	MFCMU port High (SHV) Low (SHV)
External DC bias voltage:	±3000 V
Frequency	10 kHz to 1 MHz (150 Ω at 10 kHz)
Series capacitance	110 nF ±5%
Input resistance	100 kΩ ±1%

N1259A-021 1 MΩ resistor box

N1259A-021 1 MΩ resistor box

Specification	
Input/output terminals	Ø4 mm jack (banana), 1 ea.
Resistance	1 MΩ ±5%
Maximum voltage	±3000 V
Power rating	9 W
Supplemental characteristics	
Leakage current	10 pA at 100 V

N1259A-022 100 k Ω resistor box

N1259A-022 100 k Ω resistor box

Specification	
Input/output terminals	Ø4 mm jack (banana), 1 ea.
Resistance	100 k Ω $\pm$ 5%
Maximum voltage	$\pm$ 3000 V
Power rating	6.4 W
Supplemental characteristics	
Leakage current	10 pA at 100 V

N1259A-030 1 k Ω resistor box for gate

N1259A-030 1 k Ω resistor box for gate

Specification	
Input/output terminals	Ø4 mm jack (banana), 1 ea.
Resistance	1 k Ω $\pm$ 10%
Maximum voltage	$\pm$ 200 V
Power rating	1 W
Supplemental characteristics	
Leakage current	10 pA at 100 V

N1259A-035 universal resistor box

N1259A-035 universal resistor box

Specification	
Input/output terminals	Ø4 mm banana jack, 1 ea
Resistance	Installed by a user
Maximum voltage	$\pm$ 3000 V

N1259A-300 module selector for test fixture

N1259A-300 module selector for test fixture

Specification	
Input/output terminals	HPSMU port ¹ , 1 ea. • Force, sense (Triaxial) HCSMU port, 1 ea. • Force (BNC), sense (Triaxial) HVSMU port ² , 1 ea. (HV triaxial) GNDU port, 1 ea. (Triaxial) • Digital I/O port, 1 ea. (D-sub 25 pin) • AC power line connector, 1 ea.
1. Either HPSMU or MPSMU can be connected to the HPSMU port. 2. Either HVSMU or HVMCU can be connected to the HVSMU port.	
Output terminal	High force and guard High sense and guard Low force Low sense (Ø4 mm jack (banana))
Protection	HPSMU, GNDU, HCSMU Low Force
Power indicator	LED turns yellow when AC power is applied and turns green the module selector is ready to use
Status indicator	Green LED lights to indicate the present connection path of module selector; Open, HCSMU, HPSMU, or HVSMU
Maximum voltage/current	For HPSMU port: • ± 200 V/1 A For HCSMU port: • ± 40 V/2 A, ± 20 V/30 A • (Pulse width 1 ms, duty 1%) For HVSMU: • ± 3000 V/4 mA, • ± 1500 V/2.5 A, ± 2200 V/1.1 A
Supplemental characteristics	
Leakage current	For HPSMU: • 10 pA at 200 V For HCSMU: • 100 pA at 10 V (High Force to Low Force, High Sense to Low Sense) For HVSMU: • 10 pA at 1500 V (humidity range: 20% to 70% RH) • 30 pA at 3000 V (humidity range: 20% to 50% RH)

N1260A high voltage bias-tee

N1260A high voltage bias-tee

Specification	
Input terminals	HVSMU port, 1 ea. (HV triaxial) MFCMU port, 1 ea. (4 BNC, Hp, Hc, Lp, Hc)
Output terminal	H-AC Guard (SHV connector) L-AC Guard (SHV connector)
External DC bias voltage	± 3000 V
Frequency	10 kHz to 1 MHz (150 Ω at 10 kHz)
Series capacitance	110 nF $\pm 5\%$
Input resistance	100 k Ω $\pm 1\%$

N1261A protection adapter

N1261A-001 protection adapter for HPSMU

(triaxial output)

N1261A-001 protection adapter for HPSMU (triaxial output)

Specification	
Input terminals	• Force (Triaxial) • Sense (Triaxial)
Output terminal	• Force (Triaxial) • Sense (Triaxial)
1. Either the HPSMU or the MPSMU can be connected to the HPSMU port.	
Supplemental characteristics	
Leakage current	10 pA at 200 V

N1261A-002 protection adapter for GNDU

(BNC output)

N1261A-002 protection adapter for GNDU (BNC output)

Specification	
Input terminals	Force/Sense (Triaxial)
Output terminal	• Force (BNC) • Sense (BNC)

N1261A-003 protection adapter for HPSMU

(HV triaxial output)

N1261A-003 protection adapter for HPSMU (HV triaxial output)

Specification	
Input terminals ¹	• Force (Triaxial) • Sense (Triaxial)
Output terminal	• Force (HV triaxial) • Sense (HV triaxial)
1. Either the HPSMU or the MPSMU can be connected to the HPSMU port.	
Supplemental characteristics	
Leakage current	10 pA at 200 V

N1261A-004 protection adapter for GNDU (SHV output)

N1261A-004 protection adapter for GNDU (SHV output)

Specification	
Input terminals	Force/Sense (Triaxial)
Output terminal	• Force (SHV) • Sense (SHV)

N1262A Resistor Box

N1262A-001 1 M Ω resistor box

N1262A-001 1 M Ω resistor box

Specification	
Input terminals	HVSMU port, 1 ea. (HV triaxial)
Output terminal	SHV connector, 1 ea.
Resistance	1 M Ω $\pm$ 5%
Maximum voltage	$\pm$ 3000 V
Maximum power	9 W
Supplemental characteristics	
Leakage current	10 pA at 100 V

N1262A-002 100 k Ω resistor box

N1262A-002 100 k Ω resistor box

Specification	
Input terminals	HVSMU port, 1 ea. (HV triaxial)
Output terminal	SHV connector, 1 ea.
Resistance	100 k Ω $\pm$ 5%
Maximum voltage	$\pm$ 3000 V
Maximum power	6.4 W
Supplemental characteristics	
Leakage current	10 pA at 100 V

N1262A-010 1 k Ω resistor box for gate (triaxial output)

N1262A-010 1 k Ω resistor box for the gate (triaxial output)

Specification	
Input terminals	Triaxial connector, 1 ea.
Output terminal	Triaxial connector, 1 ea.
Resistance	1 k Ω $\pm$ 10%
Maximum voltage	$\pm$ 200 V
Maximum power	1 W
Supplemental characteristics	
Leakage current	10 pA at 100 V

N1262A-011 1 kΩ resistor box for gate (SHV output)

N1262A-011 1 kΩ resistor box for the gate (SHV output)

Specification	
Input terminals	HV triaxial connector, 1 ea.
Output terminal	SHV connector, 1 ea.
Resistance	1 kΩ ±10%
Maximum voltage	±3000 V
Maximum power	1 W
Supplemental characteristics	
Leakage current	10 pA at 100 V

N1262A-020 universal resistor box, triaxial

N1262A-020 Universal resistor box, Triaxial

Specification	
Input terminals	Triaxial connector, 1 ea.
Output terminal	Triaxial connector, 1 ea.
Resistance	Installed by user
Maximum voltage for terminals	±200 V

N1262A-021 universal resistor box, HV triaxial to SHV

N1262A-021 Universal resistor box, HV Triaxial to SHV

Specification	
Input terminals	HVSMU port, 1 ea. (HV triaxial)
Output terminal	SHV connector, 1 ea.
Resistance	Installed by user
Maximum voltage for terminals	±3000 V

N1262A-023 universal resistor box for ultra high voltage

N1262A-023 Universal resistor box for Ultra High Voltage

Specification	
Input terminals	UHV coaxial connector, 1 ea.
Output terminal	UHV coaxial connector, 1 ea.
Resistance	Installed by user
Maximum voltage for terminals	±10 kV

N1262A-036 50 Ohm termination adapter

N1262A-036 50 Ohm termination adapter

Specification	
Input terminal	BNC
Output terminal	BNC
Maximum power	1 W

Accessories for N1265A

N1254A-524 ultra high current prober system cable

N1254A-524 ultra high current prober system cable

Specification	
Input terminals 8 ea. (Ø4 mm jack (banana))	Selector output • High force • High sense • Low force • Low sense • Guard Gate output • High force • Low force Chassis
Output terminals	• High force (Ø4 mm jack (banana)) • Low force (Ø4 mm jack (banana)) • High sense (HV triaxial) • Low sense (BNC) • Gate (BNC)
Maximum voltage/current	For high force • ± 3000 V/39 A (DC), 500 A (Pulse) For Low force • ± 200 V/39 A (DC), 500 A (Pulse) For High sense • ± 3000 V/1 A For low sense, gate • ± 200 V/1 A

N1265A-010 Ultra high current 3-pin inline package socket module

N1265A-010 ultra high current 3-pin inline package socket module

Specification	
Number of terminals	Sockets, 6 ea. (Ø4 mm jack (banana))
DUT interface	Inline package socket (3-pin)
Maximum voltage for terminals	3000 Vdc
Maximum current for terminals	For force • 39 A (DC), 500 A (Pulse)
	For sense • 1A (DC), 20 A (Pulse)

N1265A-011 universal socket module

N1265A-010 ultra high current 3-pin inline package socket module

Specification	
Number of terminals	Sockets, 6 ea. (Ø4 mm jack (banana))
Maximum voltage for terminals	3000 Vdc
Universal blank area	90 mm (W) x 81 mm (D)

N1265A-013 curve tracer test adapter socket module

N1265A-013 curve tracer test adapter socket module

Specification	
Number of terminals	Sockets, 6 ea. (Ø4 mm jack (banana))
Test adapter interface ¹	Sockets, 6 ea. (Ø4 mm jack (banana))
Maximum voltage at terminals	3000V Vdc
Maximum current for terminals	For collector/drain force and emitter/source force • 39 A (DC), 500 A (Pulse)
	For others • 1 A (DC), 20 A (Pulse)

1. A test adapter for Tektronix curve tracers (370B/371B) can be connected to this interface.

N1265A-014 gate charge socket adapter

Purpose

To make gate charge measurements with the N1265A.

Required hardware

- N1265A UHC expander, 1 ea.
- B1513B/C HVSMU, 1 ea.
- B1514A MCSMU, 2 ea.

N1265A-014 gate charge socket adapter

Specification	
Number of terminals	Sockets, 8 ea. (Ø4 mm jack (banana))
Maximum voltage at terminals	• For Gate DUT High: 30 V • For Gate DUT Low: 10 V • For selector force High: 3000 V • For selector force Low: 10 V • For selector sense High: 3000 V • For selector sense Low: 10 V • For SMU control High: 30 V • For SMU control Low: 10 V
Maximum current for terminals	• For Gate DUT High: 1 A • For Gate DUT Low: 1 A • For selector force: 500 A • For selector sense: 20 mA • For SMU control: 1 A

Furnished accessories

- Ultra-high current banana test lead, 2 ea.
- Test lead (red), short, 2 ea.
- Test lead (black), short, 2 ea.
- Test lead (red), long, 2 ea.
- Test lead (black), long, 2 ea.

N1265A-035 universal R-box for N1265A

N1265A-035 universal R-box for N1265A

Specification	
Input 4 ea. (Ø4 mm plug (banana))	• High (Force, Sense) • Low (Force, Sense)
Output terminals 2 ea. (Ø4 mm jack (banana))	High, Low
Resistance	Installed by a user
Maximum voltage for terminals	±200 V

N1265A-040 10 kV ultra high voltage gate protection adapter

N1265A-040 10 kV ultra high voltage gate protection adapter

Specification	
Input 4 ea. (Ø4 mm plug (banana))	• High (Force, Sense) • Low (Force, Sense)
Output terminals 2 ea. (Ø4 mm jack (banana))	High, Low
Maximum voltage	±200 V
Maximum surge voltage	±10 kV

N1265A-041 Thermocouple, Type K, 2 ea

Feature

N1265A-041 can be connected to the Thermocouple terminal inside the N1265A, enabling B1505A to read out the temperature at the top of the thermocouple.

N1265A-041 Thermocouple, Type K, 2 ea

Specification	
Connector	Type K plug
Length	3000 mm

N1265A-045 container for protection adapter and bias tee

Feature

N1265A-045 can accommodate protection adapters and bias tee, which are used with N1265A to make the measurement environment clean and safe.

N1265A-045 container for protection adapter and bias tee

Specification	
Dimension	420 mm W x 193 mm H x 565 mm D
Weight	15 kg
Maximum superimposed load	50 kg

N1269A ultra high voltage connection adapter

Feature

To simplify the connection and protect measurement resources from unexpected surges when connecting UHVU to wafer prober.

N1269A ultra high voltage connection adapter

Specification	
Input terminals	• Gate MCSMU Force, 1 ea (Triaxial) • Gate MCSMU Sense, 1 ea (Triaxial) • Chuck MCSMU Force, 1 ea (Triaxial) • Chuck MCSMU Sense, 1 ea (Triaxial) • UHV Low, 1ea (HV triaxial)
Output terminals	3ea (SHV) Gate, Chuck, Source
Maximum voltage	±200 V
Maximum surge voltage	±10 kV

N1271A Thermal Test Enclosure

Operation condition

- Temperature: +5 °C to 30 °C
- Humidity: 20% to 70% RH, Non-condensing

Accuracy specifications degrade by a factor of 3x versus measurements made without the thermal enclosure. (Supplemental characteristics)

Common furnished accessories:

- 200 mm high current cable, 2 ea.
- 300 mm high current cable, 2 ea.
- 200 mm normal cable, 6 ea.
- 300 mm normal cable, 4 ea.
- Banana pin adapter, 14 ea.
- Mini alligator clip, 10 ea.
- Large clip, 4 ea.

N1271A-001 thermal plate compatible enclosure for N1259A/N1265A

Purpose

Supports placement of the inTEST thermal plate within the test fixtures (N1259A/N1265A) to enable temperature dependency measurements up to 250 °C.

The inTest thermal plate with GP-IB control option is necessary for automated thermal measurement.

N1271A-002 thermostream compatible enclosure for N1265A (3 kV IV)

Purpose

To enable thermal testing by creating an interface between the N1265A and an inTEST thermostream. The enclosure supports fully automated IV temperature measurements from -50 °C. to +220 °C.

Specifications

Accuracy specifications degrade by a factor of 3x versus measurements made without the thermal enclosure. (Supplemental characteristics)

N1271A-002 thermostream compatible enclosure for N1265A (3 kV IV)	
Specification	
Number of channels	• SMU: 6 (When using non-Kelvin connections), 3 (When using Kelvin connections) • Gate: 1 • Selector output: 1

N1271A-005 thermostream compatible enclosure for N1265A (3 kV IV, CV & 10kV)

Purpose

To enable thermal testing by creating an interface between the N1265A and an inTEST thermostream. The enclosure supports fully automated IV and CV measurements up to 3 kV, and IV measurements up to 10 kV at a temperature ranging from -50 °C. to +220 °C.

Specifications

Accuracy specifications degrade by a factor of 3x versus measurements made without the thermal enclosure. (Supplemental characteristics)

N1271A-005 thermostream compatible enclosure for N1265A (3 kV IV, CV & 10kV)	
Specification	
Number of channels	• SMU: 4 (When using non-Kelvin connections), 2 (When using Kelvin connections) • Gate: 1 • Gate with protection resistor for UHV: 1 • Selector output: 1 • UHV: 1 • Capacitance: 1

N1273A Capacitance Test Fixture

Purpose

To enable packaged device capacitance testing in conjunction with the N1272A device capacitance Selector.

N1273A capacitance test fixture

Specification	
Input terminals	• Collector/Drain (SHV) 3000 V 20 mA • Base/Gate (SHV) 100 V 100 mA • Emitter/Source (SHV) 100 V 120 mA • AC/DC Guard (SHV) 3000 V 100 mA • Interlock port, 1 ea. • Earth terminal
High voltage indicator	• LED turns red when an SMU output is over 42 V. • Maximum voltage for SHV port: 3 kV

Furnished accessories

- System cable between selector and test fixture (SHV x 4, Interlock, Earth), 1 ea.
- 3-pin Inline Package Socket Module, 1 ea
- 200 mm normal cable, 4 ea.
- Banana pin adapter, 4 ea.
- Mini alligator clip, 4 ea.
- M5 8 mm Torx pan head screw, 2 ea.

N1273A-011 universal socket module

N1273A-011 universal socket module

Specification	
Number of terminals	Sockets, 6 ea. (Ø4 mm jack (banana))
Maximum voltage for terminals	3 kV

Furnished accessories

- Test wire for a thermal test (2 m)
- Lag connectors x 14
- Screws

N1273A-013 curve tracer test adapter socket module

N1273A-013 curve tracer test adapter socket module

Specification	
Number of terminals	Sockets, 6 ea. (Ø4 mm jack (banana)) (Sense terminals of this adapter are open. Only force terminals are connected to output terminals of N1273A.)
Maximum voltage for terminals	3 kV 100 mA Note: A test adapter for Tektronix curve tracers (370B/371B) can be connected to this interface.

N1274A On-Wafer Gate Charge Measurement Adapter/Selector for 20 A/3 kV

Purpose

To enable gate charge measurements on-wafer using the HCSMU (20 A) and HVSMU (3 kV).

Note: The connection changes to switch between IV measurement and gate charge measurement are automatically performed via high voltage/high current switches in the N1258A module selector and relays in the N1274A.

Required hardware

The following modules and accessories are required in addition to the N1274A.

- N1258A module selector
- B1512A HCSMU
- B1513B/B1513C HVSMU
- B1514A MCSMU x 2
- Current control MOSFET/IGBT

N1274A on-wafer gate charge measurement adapter/selector for 20 A/3 kV

Specification	
Input terminals (Connector) [Maximum voltage/current]	• Current control MCSMU Force (Triaxial) [±30 V/1 A] • Current control MCSMU Sense (Triaxial) [±30 V/1 A] • DUT Gate control MCSMU/HCSMU Force (Triaxial) [±30 V/1 A] • DUT Gate control MCSMU/HCSMU Sense (Triaxial) [±30 V/1 A] • High Force (HV triaxial) [±3 kV/20 A] • High Sense (HV triaxial) [±3 kV/20 A] • Low Force (BNC) [±40 V/20 A] • Low Sense (BNC) [±40 V/1 A] • Relay control port (D-sub 15 pin)
Output terminal (Connector) [Maximum voltage/current]	• High Force (banana) [±30 V/1 A] • High Sense (HV triaxial) [±30 V/1 A] • Low Force (banana) [±30 V/1 A] • Low Sense (banana) [±30 V/1 A] • Gate (BNC) [±40 V/20 A]
Supplemental characteristics	
DC leakage	• 1 nA at 3000 V (for HVSMU) • 1 nA at 100 V (for MPSMU)

- 1 nA at 200 V (for HPSMU)
 - 1 nA at 40 V (for HCSMU)
-

Furnished cables

- HCSMU cable 30 cm, 2 ea.
- HVSMU cable 35 cm, 1 ea.
- HVTraiaxial plug coax cable 35 cm, 1 ea.
- Relay control cable 30 cm, 1 ea.

N1275A On-Wafer Gate Charge Measurement Adapter for N1265A

Purpose

To enable on-wafer gate charge measurements with the UHCU (500 A) and HVSMU (3 kV)

Note: Unlike the N1274A, switching between IV and Qg requires manual connection changes.

Required hardware

The following modules and accessories are required in addition to the N1274A.

- N1265A ultra high current expander
- N1254A-524 probe system cable
- B1513B/B1513C HVSMU
- B1514A MCSMU x 2
- Current control MOSFET/IGBT

N1275A on-wafer gate charge measurement adapter for N1265A

Specification	
Input terminals (Connector) [Maximum voltage/current]	• Current control MCSMU Force (Triaxial) [± 30 V/1 A] • Current control MCSMU Sense (Triaxial) [± 30 V/1 A] • High Force from N1254A Opt524 (banana) [± 60 V/500 A] • Low Sense from N1254A Opt524 (BNC) [± 10 V/1 A] • Output terminal (Connector) [Maximum voltage/current]: • High Force to DUT (banana) [± 60 V/500 A] • Low Sense to DUT (banana) [± 10 V/1 A] • Gate (BNC) [± 40 V/20 A]

Furnished cables

- Ultra-high current banana to banana cable (30 cm), 1 ea.
- BNC cable (30 cm), 1 ea.

Keysight EasyEXPERT group+ Software

Keysight EasyEXPERT group+ GUI-based characterization software is available either on the B1505A's embedded Windows 10 platform with a 15-inch touch screen or on your PC to accelerate the characterization tasks. It supports efficient and repeatable device characterization in the entire characterization process from measurement setup and execution to analysis and data management, either interactive manual operation or automation across a wafer in conjunction with a semiautomatic wafer prober. EasyEXPERT group+ makes it easy to perform complex device characterization immediately with the hundreds of ready-to-use measurements (application tests) furnished and allows you the option of storing test condition and measurement data automatically after each measurement in a unique built-in database (workspace), ensuring that valuable information is not lost and that measurements can be repeated at a later date. Finally, EasyEXPERT has built-in analysis capabilities and a graphical programming environment that facilitate the development of complex testing algorithms.

Key features

- Multiple measurement modes for quick setup and measurement execution (application test, classic test, tracer test, quick test, and oscilloscope view)
- Graphical display, automated analysis capabilities, and data generation to Excel and image for analysis and reporting
- Built-in database (workspace) records test data automatically and simplifies the data management without numerous data files
- GUI-based self-test, self-calibration, and diagnostics menu for hardware maintenance
- EasyEXPERT group+ remote control function supports the remote measurement execution of application tests that are created on GUI interactively via the LAN interface
- Data back capability and various data protection features for shared usage by multiple users
- The characterization environment is available either on a mainframe (embedded Windows 10) or on the user's PC as a personal and portable analyzer environment. EasyEXPERT group+ can be installed on any PC as much as needed without additional charge.

Device type	Application tests
Power MOSFET (Si, GaN)	Id-Vds, Rds-Id, Id-Vgs, Vth, Cgs, Cds, Cgd, Current collapse, Breakdown, QSCV, etc.
IGBT	Ic-Vce, Ic-Vge, Vth, Cge, Cce, Cgc, Breakdown, etc.
SiC, Ga2O3	Id-Vds, Rds-Id, Id-Vgs, Vth, Cgs, Cds, Cgd, Breakdown, QSCV, etc.
Power BJT	Ic-Vce, Vce(sat), Ic-Vcbo, Ic-Vceo, Ie-Vbeo, etc.
Power Diode	If-Vf, Ir-Vr, Cj-Vr, etc.
Capacitor	C-V, C-f, C-t, Ieak-V, Breakdown, TDDb, etc.
And more	And more

Application library

EasyEXPERT group+ comes with over 40 application tests conveniently organized by device type, application, and technology. You can easily edit and customize the furnished application tests to fit your specific needs. Application tests are provided for the following categories: they are subject to change without notice.

Measurement modes and functions

Operation mode

Application test mode

The application test mode provides application-oriented point-and-click test setup and execution. An application test can be selected from the library by device type and desired measurement and then executed after modifying the default input parameters as needed.

Classic test mode

The classic test mode provides function-oriented test setup and execution with the same look, feel, and terminology as the 4155/4156 user interface. In addition, it improves the 4155/4156 user interface by taking full advantage of EasyEXPERT group+'s GUI features.

Tracer test mode

The tracer test mode offers intuitive and interactive sweep control using a rotary knob similar to a curve tracer. Just like an analog curve tracer, you can sweep in only one direction (useful for R&D device analysis) or in both directions (useful for failure analysis applications). Test setups created in tracer test mode can be seamlessly and instantaneously transferred to classic test mode for further detailed measurement and analysis. Each SMU can sweep using VAR1 (primary sweep), VAR2 (secondary sweep), or VAR1' (synchronous sweep).

Oscilloscope view

The oscilloscope view (available in tracer test mode) displays measured current or voltage data versus time. The pulsed measurement waveforms appear in a separate window for easy verification of the measurement timings. This function is useful for verifying waveform timings and debugging pulsed measurements. The following modules are supported in this view: HCSMU, MCSMU, HVSMU, UHCU, HVMCU, and UHVU. The oscilloscope view can display the pulsed waveform timings at any (user-specified) sweep step of the sweep output.

Sampling interval:

- 2 μ s (HCSMU/MCSMU/UHCU/HVMCU/UHVU)
- 6 μ s (HVSMU)

Sampling points:

- 2000 Sa (HCSMU/MCSMU/UHCU/HVMCU/UHVU)
- 4000 Sa (HVSMU)

Marker function: Read-out for each data channel

Resolution: 2 μ s

Data saving:

- Numeric: Text/CSV/XMLSS
- Image: EMF/BMP/JPG/PNG

Quick test mode

A GUI-based Quick Test mode enables you to perform test sequencing without programming. You can select, copy, rearrange, and cut-and-paste any application tests with a few simple mouse clicks. Once you have selected and arranged your tests, simply click the measurement button to run an automated test sequence.

Measurement modes:

The Keysight B1505A supports the following measurement modes:

- IV measurement
 - Spot
 - Staircase sweep
 - Pulsed spot
 - Pulsed sweep
 - Staircase sweep with pulsed bias
 - Sampling
 - Multi-channel sweep
 - Multi-channel pulsed sweep
 - List sweep
 - Linear search¹
 - Binary search¹
- C measurement
 - Spot C
 - CV (DC bias) sweep
 - Pulsed spot C

- Pulsed sweep CV
- C-t sampling
- C-f sweep
- CV (AC level) sweep
- Quasi-Static CV (QSCV)

1. Supported only by FLEX commands.

Sweep measurement

- Number of steps: 1 to 10001 (SMU), 1 to 1001 (CMU)
- Sweep mode: Linear or logarithmic (log)
- Sweep direction: Single or double sweep
- Hold time: 0 to 655.35 s, 10 ms resolution
- Delay time: 0 to 65.535 s, 100 μ s resolution 0 to 655.35 s, 100 μ s resolution (CV (AC level) sweep, C-f sweep)
- Step delay time: 0 to 1 s, 100 μ s resolution
- Step output trigger delay time: 0 to (delay time) s, 100 μ s resolution
- Step measurement trigger delay time: 0 to 65.535 s, 100 μ s resolution

Recommended GPIB I/F

		Interface	B1505A
Keysight	82350B/C	PCI	Yes ¹
	82357A	USB	Yes ²
	82357B	USB	Yes ²
National instrument	GPIB-USB-HS	USB	Yes ²

1. An 82350B/C card is highly recommended because of its stability and speed.

2. USB GPIB interfaces might cause serial poll errors intermittently due to the intrinsic communication scheme differences. It is reported that using an even GPIB address sometimes significantly decreases the chance of the error. The NI GPIB-USB-HS is recommended for stability, and the Keysight 82357B is recommended for speed.

Sampling (time domain) measurement

Displays the time sampled voltage/current data (by SMU) versus time.

- Sampling channels: Up to 10
- Sampling mode: Linear, logarithmic (log)
- Sampling points:
 - For linear sampling: 1 to 100,001/(number of channels)
 - For log sampling: 1 to 1+ (number of data for 11 decades)
- Sampling interval range:
 - 100 μ s to 2 ms, 10 μ s resolution
 - 2 ms to 65.535 s, 1 ms resolution
 - For < 2 ms, the interval is $\geq 100 \mu\text{s} + 20 \mu\text{s} \times (\text{num. of channels} - 1)$
 - Hold time, initial wait time:
 - -90 ms to -100 μ s, 100 μ s resolution
 - 0 to 655.35 s, 10 ms resolution
- Measurement time resolution: 100 μ s

Other measurement characteristics

Measurement control

- Single, repeat, append and stop

SMU setting capabilities

- Limited auto-ranging, voltage/current compliance, power compliance, automatic sweep abort functions, self-test, and self-calibration

Standby mode

- SMUs in “Standby” remain programmed to their specified output value even as other units are reset for the next measurement.

Bias hold function

- This function allows you to keep a source active between measurements. The source module will apply the specified bias between measurements when running classic tests inside an application test, in quick test mode, or during a repeated measurement. The function ceases as soon as these conditions end or when a measurement that does not use this function is started.

Current offset cancel

- This function subtracts the offset current from the current measurement raw data and returns the result as the measurement data. This function is used to compensate the error factor (offset current) caused by the measurement path, such as the measurement cables, manipulators, or probe card.

Timestamp

- The B1505A supports a time stamp function utilizing an internal quartz clock.
Resolution: 100 μ s

Data display, analysis and arithmetic functions

Data display

X-Y graph plot

X-axis and up to eight Y-axes, linear and log scale, and real time graph plotting. X-Y graph plots can be printed or stored as image data on a clipboard or mass storage device. (File type: bmp, gif, png, emf)

Scale: Auto scale and zoom

Marker: Marker to min/max, interpolation, direct marker, and marker skip

Cursor: Direct cursor

Line: Two lines, normal mode, grad mode, tangent mode, and regression mode.

Overlay graph comparison: Graphical plots can be overlaid.

List display

Measurement data and calculated user function data are listed in conjunction with the sweep step number or time domain sampling step number. Up to 20 data sets can be displayed.

Data variable display

Up to 20 user-defined parameters can be displayed on the graphics screen.

Automatic analysis function

On a graphics plot, the markers and lines can be automatically located using the auto analysis setup. Parameters can be automatically determined using automatic analysis, user function, and read-out functions.

Analysis functions

Up to 20 user-defined analysis functions can be defined using arithmetic expressions. Measured data, pre-defined variables, and read-out functions can be used in the computation. The results can be displayed on the LCD.

Read out functions

The read-out functions are built-in functions for reading various values related to the marker, cursor, or line

Arithmetic functions

User functions

Up to 20 user-defined functions can be defined using arithmetic expressions. Measured data and predefined variables can be used in the computation. The results can be displayed on the LCD.

Arithmetic operators

+, -, *, /, ^, abs (absolute value), at (arc tangent), avg (averaging), cond (conditional evaluation), delta, diff (differential), exp (exponent), integ (integration), lgt (logarithm, base 10), log (logarithm, base e), mavg (moving average), max, min, sqrt, trigonometric function, inverse trigonometric function, and so on.

Physical constants

Keyboard constants are stored in memory as follows:

- q: Electron charge, 1.602177E-19 C
- k: Boltzmann's constant, 1.380658E-23
- ϵ (e): Dielectric constant of vacuum, 8.854188E-12

Engineering units

The following unit symbols are also available on the keyboard:

- a (10^{-18}), f (10^{-15}), p (10^{-12}), n (10^{-9}), u or μ (10^{-6}), m (10^{-3}), k (10^3), M (10^6), G (10^9), T (10^{12}), P (10^{15})

Data management

Workspace (Built-in database)

EasyEXPERT group+ supports the built-in database called “workspace”. Workspaces are created on an SSD, enabling managing and accessing all the measurement-related data without handling numerous files. Every workspace supports the following features:

- Access to measurement capabilities and data stored in the workspace.
- Save/Import/Export measurement settings and data (application library, measurement settings, my favorite setup, and measurement data)
- Recall the setup for measurement reproduction and data for analysis

Data auto record/ auto export

EasyEXPERT group+ has the ability to automatically store the measurement setup and data within a workspace. It can also export measurement data in real-time in a variety of formats such as Excel (xls).

Import/export files

File type:

- Keysight EasyEXPERT format, XML-SS format, CSV format

Data protection

EasyEXPERT group+ has various options to protect important data, as follows.

- Password protection (workspace, test definition, and my favorite)
- User-level access control (engineer mode/operator mode)

Workspace backup and portability

EasyEXPERT group+ has the ability to import/export a workspace for backup and portability.

General specification

General specification

Temperature range	- Operating: +5 °C to +40 °C - Storage: -20 °C to +60 °C
Humidity range¹	- Operating: 20% to 70% RH, non-condensing - Storage: 10% to 90% RH, non-condensing - Storage: 20% to 80% RH, non-condensing (N1268A)
Altitude	Operating: 0 m to 2,000 m (6,561 ft) Storage: 0 m to 4,600 m (15,092 ft) 0 m to 2,000 m (6,561 ft) (N1268A)
Power requirement	- ac Voltage: 90 V to 264 V - Line Frequency: 47 Hz to 63 Hz
Maximum volt-amps (VA)	- B1505A: 900 VA - N1258A: 65 VA - N1259A-300: 35 VA - N1265A: 400 VA - N1266A: 60 VA - N1268A: 350 VA - N1272A: 70 VA
Acoustic Noise Emission	- Lpa < 65 dB - Lwa: 66 dB (Operating mode) - Lwa: 73 dB (Worst case mode)
About measurement accuracy	RF electromagnetic field and SMU measurement accuracy: SMU voltage and current measurement accuracy can be affected by RF electromagnetic field strengths greater than 3 V/m in the frequency range of 80 MHz to 1 GHz. The extent of this effect depends upon how the instrument is positioned and shielded. Induced RF field noise and SMU measurement accuracy: SMU voltage and current measurement accuracy can be affected by induced RF field noise strengths greater than 3 Vrms in the frequency range of 150 kHz to 80 MHz. The extent of this effect depends upon how the instrument is positioned and shielded.
Regulatory compliance	EMC: - IEC 61326-1 / EN 61326-1 - Canada: ICES/NMB-001 - AS/NZS CISPR 11 Safety: - IEC61010-1 / EN 61010-1 - CAN/CSA-C22.2 No. 61010-1
Certification	CE, cCSAus, RCM

Dimensions

B1505A:

- 420 mm W x 330 mm H x 575 mm D

N1258A module selector:

- 330 mm W x 120 mm H x 410 mm D

N1259A test fixture:

- 420 mm W x 272 mm H x 410 mm D

N1260A High voltage bias-tee:

- 164 mm W x 53 mm H x 125 mm D

N1261A-001 HPSMU protection adapter (Triaxial output):

- 80 mm W x 40 mm H x 110 mm D

N1261A-002 GNDU protection adapter (BNC output):

- 80 mm W x 40 mm H x 110 mm D

N1261A-003 HPSMU protection adapter (HV triaxial output):

- 90 mm W x 40 mm H x 140 mm D

N1261A-004 GNDU protection adapter (SHV output):

- 80 mm W x 40 mm H x 125 mm D

N1262A resistor box:

- 50 mm W x 40 mm H x 125 mm D

N1265A UHC expander/fixture:

- 420 mm W x 285 mm H x 575 mm D

N1266A HVSMU current expander:

- 420 mm W x 75 mm H x 575 mm D

N1267A HVSMU / HCSMU fast switch:

- 202 mm W x 56 mm H x 175 mm D

N1268A UHV expander:

- 420 mm W x 222 mm H x 482 mm D

N1269A Ultra High Voltage Connection Adapter:

- 134 mm W x 56 mm H x 150 mm D

N1271A-001 Thermal plate compatible enclosure for N1259A/N1265A

- 500 mm W x 190 mm H x 365 mm D

N1271A-002 Thermostream compatible enclosure for N1265A (3kV IV)

- 330 mm W x 340 mm H x 430 mm D (Outer dimension)

- 284 mm W x 150 mm H x 195 mm D (Inner dimension)

N1271A-005 Thermostream compatible enclosure for N1265A (3kV IV, CV & 10kV)

- 330 mm W x 340 mm H x 430 mm D (Outer dimension)

- 275 mm W x 150 mm H x 195 mm D (Inner dimension)

N1272A:

- 420 mm W x 75 mm H x 575 mm D

N1273A:

- 340 mm W x 200 mm H x 345 mm D

N1274A:

- 330 mm W x 90 mm H x 410 mm D

N1275A:

- 116 mm W x 78 mm H x 125 mm D

Weight

- B1505A (empty): 20 kg
 - B1511B: 1.1 kg
 - B1510A: 2.0 kg
 - B1512A: 2.1 kg
 - B1513C: 2.0 kg
 - B1514A: 1.3 kg
 - B1520A: 1.3 kg
 - N1258A: 5.0 kg
 - N1259A: 12.0 kg
 - N1260A: 0.6 kg
-

- N1261A: 0.3 kg
- N1262A: 0.3 kg
- N1265A: 30 kg
- N1266A: 10 kg
- N1267A: 0.8 kg
- N1268A: 18 kg
- N1269A: 0.4 kg
- N1271A-001: 4.5 kg
- N1271A-002: 10.5 kg
- N1271A-005: 10.5 kg
- N1272A: 9.4 kg
- N1273A: 0.7 kg
- N1274A: 3.2 kg
- N1275A: 0.4 kg

Furnished accessories

- Measurement cables and adapter
 - Triaxial cable for HPSMU, MPSMU, and MCSMU, 2 ea.
 - HCSMU cable, 1 ea.
 - HCSMU Kelvin adapter, 1 ea.
 - HVSMU cable, 1 ea.
 - Interlock cable, 1 ea.
 - Ground unit cable, 1 ea.
 - Keyboard, 1 ea.
 - Mouse, 1 ea.
 - Stylus pen, 1 ea.
 - Power cable, 1 ea.
 - Software entitlement document for EasyEXPERT group+
 - SMU number label for the B1505A installed with SMU, 1 sheet
 - N1258A: Digital I/O cable, 1 ea.
 - N1259A-300: Digital I/O cable, 1 ea.
 - N1265A: Digital I/O cable, 1 ea.
 - N1266A: Digital I/O cable, 1 ea.
 - N1268A: Digital I/O cable, 1 ea., Interlock cable, 1 ea.
 - N1272A: Digital I/O cable 1.5m, 1 ea HVSMU cable 1.5 m, 1 ea.
-

Order Information

Mainframe and modules

B1505A	Power device analyzer/Curve tracer mainframe
	Configure the following modules: • High-power SMU (HPSMU) • Medium power SMU (MPSMU) • High current SMU (HCSMU) • Medium current SMU (MCSMU) • High voltage SMU (HVSMU) • Multi-frequency CMU (MFCMU)
B1505A-015	1.5 m cable
B1505A-030	3.0 m cable
B1505A-050	50 Hz line frequency
B1505A-060	60 Hz line frequency
B1505A-A6J	ANSI Z540 compliant calibration
B1505A-UK6	Commercial calibration certificate with test data
B1500A-1CM	Rackmount kit

B1505A expanders/fixtures

N1259A	Test fixture
N1259A-010	Inline package socket module (3-pin)
N1259A-011	Universal socket module
N1259A-012	Blank PTFE board
N1259A-013	Curve Tracer test adaptor socket module
N1259A-014	Gate Charge socket adapter
N1259A-020	High voltage bias-tee
N1259A-021	1 MΩ Resistor box
N1259A-022	100 kΩ Resistor box
N1259A-030	1 kΩ Resistor box for gate
N1259A-035	Universal R-Box
N1259A-300	Module selector
N1265A	UHC expander/fixture
N1265A-010	500 A Ultra High Current 3-pin Inline Package Socket Module
N1265A-011	Universal Socket Module
N1265A-013	Curve Tracer Test Adapter Socket Module
N1265A-014	Gate Charge socket adapter
N1265A-015	1500 A Current Option
N1265A-035	Universal R-Box for N1265A
N1265A-040	10 kV Ultra High Voltage Gate Protection Adapter
N1265A-041	Thermocouple, Type K, 2 ea
N1265A-045	Container for Protection Adapter and Bias Tee
N1266A	High Voltage Source Monitor Unit Current Expander
N1267A	High Voltage Source Monitor Unit / High Current Source Monitor Unit Fast Switch

N1268A	Ultra-High Voltage Expander
N1271A	Thermal Test Enclosure
N1271A-001	Thermal plate compatible enclosure for N1259A/N1265A
N1271A-002	Thermostream compatible enclosure for N1265A (3kV IV)
N1271A-005	Thermostream compatible enclosure for N1265A (3kV IV, CV & 10kV)
N1272A	Device Capacitance Selector
N1273A	Capacitance Test Fixture
N1273A-011	Universal Socket Module
N1273A-013	Curve Tracer Test Adapter Socket Module
N1274A	On-Wafer Gate Charge measurement adapter/selector for 20 A/3 kV
N1275A	On-Wafer Gate Charge measurement adapter for N1265A

B1505A accessories

16444A-001	Keyboard
16444A-002	Mouse
16444A-003	Stylus pen
N1253A-100	Digital I/O cable
N1253A-200	Digital I/O BNC box
N1254A-100	Ground unit Kelvin adapter
N1254A-101	Triaxial(m)-BNC(f)
N1254A-102	Triaxial(m)-BNC(m)
N1254A-103	Triaxial(m)-BNC(f)
N1254A-104	Triaxial(f)-BNC(m)
N1254A-105	Triaxial(f)-BNC(m)
N1254A-106	Triaxial(m)-BNC(f)
N1254A-107	Triaxial(m)-BNC(f)
N1254A-500	HV Jack Connector (Solder Type)
N1254A-501	HV Jack /Jack Adapter
N1254A-502	HV plug Connector (Solder Type)
N1254A-503	BNC Coax Cable Assy 1.5m(Open End)
N1254A-504	HVTriax Jack Coax Cable Assy 1.5m(Open End)
N1254A-505	HVTriax Plug Triax Cable Assy 1.5m (Open End)
N1254A-506	HVTriax Plug Coax Cable Assy 1.5m(Open End)
N1254A-507	HVTriax Plug Coax Cable Assy 1.5m
N1254A-508	Test Lead cable Black
N1254A-509	Test Lead cable Red
N1254A-510	Dolphin clip 2 ea. (red and black)
N1254A-511	Cable lag adapter 2 ea. (red and black)
N1254A-512	SHV Cable Assy 250 mm
N1254A-513	SHV to Banana
N1254A-514	BNC-Plug Plug
N1254A-515	BNC-Jack-Plug-Jack
N1254A-516	BNC-Jack-Jack-Jack
N1254A-517	Adapter, Triaxial Jack to Triaxial Plug

N1254A-518	SHV Cable 1.5 m
N1254A-520	10 kV Ultra High Voltage Open End Cable, 1 m.
N1254A-521	10 kV Ultra High Voltage Jack-to-Jack Adapter
N1254A-522	1500 A Ultra High Current Banana to Banana Cable, 2 ea.
N1254A-523	1500 A Ultra High Current Banana to Open End Cable, 1 m, 2 ea
N1254A-524	Ultra-High Current Prober System Cable
N1254A-525	SHV Cable Assy 1.5m - SHV Plug To Open-end
N1254A-526	Ultra-High Current Cable, 2m, No Connectors At Either End
N1254A-527	PTFE Standoff, Jack, 4 ea.
N1254A-528	PTFE Standoff With Banana Plug, 4 ea.
N1254A-556	Test Leads and Connection Kit for Capacitance Test, 30 cm, 4 ea.
N1254A-557	Test Leads And Connection Kit For Thermal Test with N1271A
N1254A-558	SHV Cable 3m
N1258A	Module selector
N1260A	High voltage bias-tee
N1261A	Protection adapter
N1262A	Resistor box
N1262A-020	Universal R-Box, Triaxial
N1262A-021	Universal R-Box, HV Triaxial to SHV
N1262A-023	Universal R-Box for Ultra High Voltage
N1262A-036	50 Ohm Termination Adapter

SMU cables/accessories

16493S-001	HCSMU cable (1.5 m)
16493S-002	HCSMU cable (3 m)
16493S-010	HCSMU Kelvin adapter
16493S-011	HCSMU non-Kelvin adapter
16493S-020	Dual HCSMU Kelvin combination adapter
16493S-021	Dual HCSMU combination adapter
16493T-001	High voltage triaxial cable (1.5 m)
16493T-002	High voltage triaxial cable (3 m)
16493U-001	High current BNC cable (1.5 m)
16493U-002	High current BNC cable (3 m)
16494A-001	Triaxial cable (1.5 m)
16494A-002	Triaxial cable (3 m)
16493K-001	Kelvin triaxial cable (1.5 m)
16493K-002	Kelvin triaxial cable (3 m)
16493V-001	10 kV Ultra High Voltage Cable, 1.5 m
16493V-002	10 kV Ultra High Voltage Cable, 3 m
N1269A	Ultra-High Voltage Connection Adapter

CMU accessories

N1300A-001	CMU cable (1.5 m)
N1300A-002	CMU cable (3 m)

Other accessories

16493G-001	Digital I/O cable (1.5 m)
16493G-002	Digital I/O cable (3 m)
16493J-001	Interlock cable (1.5 m)
16493J-002	Interlock cable (3 m)
16493L-001	GNDU cable (1.5 m)
16493L-002	GNDU cable (3 m)

Retrofit and upgrade kits

B1505AU	Upgrade kit for B1505A
B1505AU-001	Conversion kit from B1500A to B1505A
B1500AU-PC2	Mainframe upgrade (available for S/N starts with JP or less than MY53440000)
B1500AU-PC3	Mainframe upgrade (available for S/N MY53440101 or later)
B1505AU-010	High power source monitor unit (B1510A)
B1505AU-11B	Medium power source monitor unit (B1511B)
B1505AU-012	High current source monitor unit (B1512A)
B1505AU-13C	High voltage source monitor unit (B1513C)
B1505AU-014	Medium current source monitor unit (B1514A)
B1505AU-020	Multi-frequency capacitance measurement unit (B1520A)
B1505AU-SWS	EasyEXPERT group+ Extension support and subscription
N1259AU	Upgrade kit for N1259A
N1265AU	Upgrade kit for N1265A

Package solution

B1505AP	Pre-configured Power Device Analyzer/Curve Tracer (B1505A w/ modules/fixture)
B1505AP-H20	3 kV / 20 A / Fixture Pack
B1505AP-H21	3 kV / 20 A / C-V / Fixture Pack
B1505AP-H50	3 kV / 500 A / Fixture Pack
B1505AP-H51	3 kV / 500 A / C-V / Fixture Pack
B1505AP-H70	3 kV / 1500 A / Fixture Pack
B1505AP-H71	3 kV / 1500 A / C-V / Fixture Pack
B1505AP-U50	10 kV / 500 A / Fixture Pack
B1505AP-U70	10 kV / 1500 A / Fixture Pack

Conclusion

The B1505A is a highly versatile power device evaluation tool with advanced features such as fast pulsing, high voltage bias measurements, and automated capacitance measurements. It also includes EasyEXPERT group+ software for efficient and repeatable device characterization, with hundreds of ready-to-use measurements and a built-in database for storing test conditions and measurement data.

If you need a reliable and powerful tool for power device evaluation and characterization, consider the B1505A with EasyEXPERT group+ software. It can help you efficiently perform complex measurements, improve data analysis and management, and ultimately accelerate your device development and testing.



Mess- und Prüftechnik. Die Experten.

**Ihr Ansprechpartner /
Your Partner:**

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